

(19)



(11)

EP 3 716 265 B1

(12)

EUROPEAN PATENT SPECIFICATION

(45) Date of publication and mention of the grant of the patent:
18.06.2025 Bulletin 2025/25

(21) Application number: **18881899.1**

(22) Date of filing: **20.11.2018**

(51) International Patent Classification (IPC):
G10K 11/178 ^(2006.01) **G10K 9/122** ^(2006.01)
E04B 1/82 ^(2006.01) **B06B 1/06** ^(2006.01)
H04R 17/00 ^(2006.01) **H04R 7/04** ^(2006.01)

(52) Cooperative Patent Classification (CPC):
B06B 1/0688; G10K 9/122; G10K 11/1785;
G10K 11/17881; H04R 17/00; G10K 11/17861;
G10K 2210/118; G10K 2210/3212;
G10K 2210/32291; G10K 2210/509; H04R 7/045;
H04R 2440/05

(86) International application number:
PCT/JP2018/042909

(87) International publication number:
WO 2019/103017 (31.05.2019 Gazette 2019/22)

(54) **ACTIVE NOISE CONTROL SYSTEM**

AKTIVES GERÄUSCHDÄMPFUNGSSYSTEM
SYSTÈME ACTIF DE CONTRÔLE DU BRUIT

(84) Designated Contracting States:
AL AT BE BG CH CY CZ DE DK EE ES FI FR GB
GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO
PL PT RO RS SE SI SK SM TR

(30) Priority: **21.11.2017 JP 2017223799**

(43) Date of publication of application:
30.09.2020 Bulletin 2020/40

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Description

TECHNICAL FIELD

- 5 **[0001]** The present invention relates to a sound reducing system, and specifically relates to a sound reducing system including at least one sound reducing speaker for radiating a sound wave for sound reduction.

BACKGROUND ART

- 10 **[0002]** Speakers employing a piezoelectric film (such speakers may hereinafter be referred to as piezoelectric speakers) have been known. Piezoelectric speakers have an advantage in that they are small in volume and light.
[0003] Patent Literature 1 describes using a piezoelectric speaker as a sound reducing speaker to configure a sound reducing system. Specifically, in this sound reducing system, a piezoelectric film is directly stuck using an adhesive to a wooden board serving as a wall material which is a support.

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CITATION LIST

[0004] Patent Literature

- 20 Patent Literature 1: JP H06-236189 A
 Patent Literature 2: JP 2016-122187 A
 Patent Literature 3: JP-2005-010270
 Patent Literature 4: WO 2017/002573
 Patent Literature 5: TW 201347564
 25 Patent Literature 6: US 2009/245546
 Patent Literature 7: WO 2017/126257

SUMMARY OF INVENTION

30 Technical Problem

[0005] The present invention aims to provide a sound reducing system well radiating a sound wave for sound reduction from a piezoelectric film.

35 Solution to Problem

[0006] According to a study by the present inventors, sound in the audible range is easily emitted from a piezoelectric film when an appropriate layer is interposed between the piezoelectric film and a support. An adhesive for fixing the piezoelectric film is also interposed between the piezoelectric film and the support (Patent Literature 1). However, the reproducibility of an implementation of such interposition is low because the adhesive is applied at a place where a sound reducing system should be built. Therefore, an adhesive applied to a piezoelectric film to fix the piezoelectric film to a support is, at least by itself, not suitable for improving a sound reducing system employing a piezoelectric speaker.

40 **[0007]** Patent Literature 3 describes an oscillation noise reducing system mounted with a piezoelectric speaker as an acousto-electric transducer or oscillation-electricity transducer on a suppression object, equipped with an energy consuming means which converts the electric energy obtained from the piezoelectric speaker to thermal energy and consumes the thermal energy. Patent Literature 4 describes an electro-acoustic converter that includes two electro-acoustic converting units each comprising: an electro-acoustic converting film including a polymer composite piezoelectric body formed by dispersing piezoelectric particles in a viscoelastic matrix comprising a polymer material that is viscoelastic at room temperature, and two thin-film electrodes laminated onto the two surfaces of the polymer composite piezoelectric body; and a resilient supporting body which is disposed in close contact with one of the main surfaces of the electro-acoustic converting film in such a way as to cause the electro-acoustic converting film to curve to form a curved portion. Patent Literature 5 describes a composite piezoelectric vibrator that includes a polymer film composed of fiber, lightweight foam and pressure sensitive adhesive that are combined together by an adhesive and a piezoelectric actuator adhered to surface of the polymer film or embedded in the polymer film. Patent Literature 6 describes a film-type audio-speaker that uses a piezoelectric film as a vibration element to provide a reinforcement of the low to medium frequency band sound waves generated. The film-type audio-speaker uses a piezoelectric film as a vibration element and comprises a piezoelectric film with an electrically conductive polymer or metal layer coated on its surface, a terminal portion electrically connected to the piezoelectric film; and an audio-speaker driving unit connected to the terminal portion. Patent Literature 7

describes an electroacoustic transducer includes: an electroacoustic transduction unit having an electroacoustic transduction film including a polymer composite piezoelectric body in which piezoelectric body particles are dispersed in a viscoelastic matrix formed of a polymer material having viscoelasticity at a normal temperature and thin film electrodes respectively laminated on both surfaces of the polymer composite piezoelectric body, and an elastic support disposed in close contact with one principal surface to bend the shape of the electroacoustic transduction film; and a first cushion layer that is in contact with the electroacoustic transduction film on an electroacoustic transduction film side of the electroacoustic transduction unit to cover the electroacoustic transduction unit and is formed of a three-dimensional solid knitted fabric.

[0008] The present invention provides a sound reducing system as defined in appended claim 1.

Advantageous Effects of Invention

[0009] The above sound reducing system is suitable for well radiating a sound wave for sound reduction from a piezoelectric film.

BRIEF DESCRIPTION OF DRAWINGS

[0010]

FIG. 1 is a cross-sectional view showing a piezoelectric speaker cut along the thickness direction thereof.

FIG. 2 is a top view showing a piezoelectric speaker viewed from the side opposite to a fixing face.

FIG. 3 is a schematic diagram illustrating a sound reducing system.

FIG. 4 is a diagram showing a piezoelectric speaker according to another embodiment.

FIG. 5 is a diagram illustrating a structure produced in an example.

FIG. 6 is a diagram illustrating a structure for measurement of a sample.

FIG. 7 is a diagram illustrating a structure for measurement of a sample.

FIG. 8 is a block diagram of an output system.

FIG. 9 is a block diagram of an evaluation system.

FIG. 10A is a table showing the results of evaluation of samples.

FIG. 10B is a table showing the results of evaluation of samples.

FIG. 11 is a graph showing a relationship between the holding degree of an interposed layer and a frequency at which emission of sound starts.

FIG. 12 is a graph showing the frequency characteristics of a sample of Example 1 in terms of sound pressure level.

FIG. 13 is a graph showing the frequency characteristics of a sample of Example 2 in terms of sound pressure level.

FIG. 14 is a graph showing the frequency characteristics of a sample of Example 3 in terms of sound pressure level.

FIG. 15 is a graph showing the frequency characteristics of a sample of Example 4 in terms of sound pressure level.

FIG. 16 is a graph showing the frequency characteristics of a sample of Example 5 in terms of sound pressure level.

FIG. 17 is a graph showing the frequency characteristics of a sample of Example 6 in terms of sound pressure level.

FIG. 18 is a graph showing the frequency characteristics of a sample of Example 7 in terms of sound pressure level.

FIG. 19 is a graph showing the frequency characteristics of a sample of Example 8 in terms of sound pressure level.

FIG. 20 is a graph showing the frequency characteristics of a sample of Example 9 in terms of sound pressure level.

FIG. 21 is a graph showing the frequency characteristics of a sample of Example 10 in terms of sound pressure level.

FIG. 22 is a graph showing the frequency characteristics of a sample of Example 11 in terms of sound pressure level.

FIG. 23 is a graph showing the frequency characteristics of a sample of Example 12 in terms of sound pressure level.

FIG. 24 is a graph showing the frequency characteristics of a sample of Example 13 in terms of sound pressure level.

FIG. 25 is a graph showing the frequency characteristics of a sample of Example 14 in terms of sound pressure level.

FIG. 26 is a graph showing the frequency characteristics of a sample of Example 15 in terms of sound pressure level.

FIG. 27 is a graph showing the frequency characteristics of a sample of Example 16 in terms of sound pressure level.

FIG. 28 is a graph showing the frequency characteristics of a sample of Example 17 in terms of sound pressure level.

FIG. 29 is a graph showing the frequency characteristics of a sample of Reference Example 1 in terms of sound pressure level.

FIG. 30 is a graph showing the frequency characteristics of background noise in terms of sound pressure level.

FIG. 31 illustrates a supporting structure of a piezoelectric film.

DESCRIPTION OF EMBODIMENTS

[0011] Hereinafter, embodiments of the present invention will be described with reference to the accompanying drawings.

[First embodiment]

[0012] A piezoelectric speaker according to a first embodiment will be described using FIG. 1 and FIG. 2. A piezoelectric speaker 10 includes a piezoelectric film 35, a fixing face 17, and a film holding portion 55. The fixing face 17 is used for fixing the piezoelectric film 35 to a support.

[0013] The film holding portion 55 is disposed between the piezoelectric film 35 and the fixing face 17. The film holding portion 55 includes an interposed layer 40, a pressure-sensitive adhesive or adhesive layer 51 (which may hereinafter be simply referred to as a pressure-sensitive adhesive layer 51), and a pressure-sensitive adhesive or adhesive layer 52 (which may hereinafter be simply referred to as a pressure-sensitive adhesive layer 52). In the example in FIG. 1, the fixing face 17 is formed of a surface (principal surface) of the pressure-sensitive adhesive layer 51. That is, the fixing face 17 is a pressure-sensitive adhesive face or an adhesive face.

[0014] The piezoelectric film 35 includes a piezoelectric body 30, an electrode 61, and an electrode 62. The pressure-sensitive adhesive layer 51, the interposed layer 40, the pressure-sensitive adhesive layer 52, and the piezoelectric film 35 are laminated in this order.

[0015] Hereinafter, the pressure-sensitive adhesive layer 51 may be referred to as a first pressure-sensitive adhesive layer 51, the pressure-sensitive adhesive layer 52 may be referred to as a second pressure-sensitive adhesive layer 52, the electrode 61 may be referred to as a first electrode 61, and the electrode 62 may be referred to as a second electrode 62.

[0016] The piezoelectric body 30 has the shape of a film. The piezoelectric body 30 is vibrated by application of voltage. A ceramic film, a resin film, and the like can be used as the piezoelectric body 30. Examples of the material of the piezoelectric body 30 that is a ceramic film include lead zirconate, lead zirconate titanate, lead lanthanum zirconate titanate, barium titanate, Bi-layered compounds, compounds having a tungsten bronze structure, and solid solutions of barium titanate and bismuth ferrite. Examples of the material of the piezoelectric body 30 that is a resin film include polyvinylidene fluoride and polylactic acid. The material of the piezoelectric body 30 that is a resin film may be a polyolefin such as polyethylene or polypropylene. The piezoelectric body 30 may be a non-porous body or may be a porous body.

[0017] The thickness of the piezoelectric body 30 is, for example, 10 μm to 300 μm and may be 30 μm to 110 μm .

[0018] The first electrode 61 and the second electrode 62 are in contact with the piezoelectric body 30 so as to sandwich the piezoelectric body 30. The first electrode 61 and the second electrode 62 each have the shape of a film. The first electrode 61 and the second electrode 62 are each connected to a lead wire which is not illustrated. The first electrode 61 and the second electrode 62 can be formed on the piezoelectric body 30 by vapor deposition, plating, sputtering, or the like. A metal foil can be used as each of the first electrode 61 and the second electrode 62. A metal foil can be stuck to the piezoelectric body 30 using a double-faced tape, a pressure-sensitive adhesive, an adhesive, or the like. Examples of the materials of the first electrode 61 and the second electrode 62 include metals, and specific examples thereof include gold, platinum, silver, copper, palladium, chromium, molybdenum, iron, tin, aluminum, and nickel. Examples of the materials of the first electrode 61 and the second electrode 62 also include carbon and electrically conductive polymers. Examples of the materials of the first electrode 61 and the second electrode 62 also include alloys of the above metals. The first electrode 61 and the second electrode 62 may include, for example, a glass component.

[0019] The thickness of the first electrode 61 and that of the second electrode 62 are each, for example, 10 nm to 150 μm , and may be 20 nm to 100 μm .

[0020] In the example in FIG. 1 and FIG. 2, the first electrode 61 covers one entire principal surface of the piezoelectric body 30. The first electrode 61 may cover only a portion of the one principal surface of the piezoelectric body 30. The second electrode 62 covers the other entire principal surface of the piezoelectric body 30. The second electrode 62 may cover only a portion of the other principal surface of the piezoelectric body 30.

[0021] The interposed layer 40 is disposed between the piezoelectric film 35 and the fixing face 17. In the present embodiment, the interposed layer 40 is disposed between the piezoelectric film 35 and the first pressure-sensitive adhesive layer 51. The interposed layer 40 may be a layer other than an adhesive layer and a pressure-sensitive adhesive layer, or may be an adhesive layer or a pressure-sensitive adhesive layer. The interposed layer 40 is a porous body layer and/or a resin layer. Here, the resin layer is a concept including a rubber layer and an elastomer layer. Therefore, the interposed layer 40 that is a resin layer may be a rubber layer or an elastomer layer. Examples of the interposed layer 40 that is a resin layer include an ethylene propylene rubber layer, a butyl rubber layer, a nitrile rubber layer, a natural rubber layer, a styrene-butadiene rubber layer, a silicone layer, a urethane layer, and an acrylic resin layer. Examples of the interposed layer 40 that is a porous body layer include foam layers. Specifically, examples of the interposed layer 40 that is a porous body layer and a resin layer include an ethylene propylene rubber foam layer, a butyl rubber foam layer, a nitrile rubber foam layer, a natural rubber foam layer, a styrene-butadiene rubber foam layer, a silicone foam layer, and a urethane foam layer. Examples of the interposed layer 40 that is not a porous body layer but a resin layer include acrylic resin layers. Examples of the interposed layer 40 that is not a resin layer but a porous body layer include porous metal body layers. The term "resin layer" as used herein refers to a resin-including layer. The term "resin layer" as used herein refers to a layer that may include a resin in an amount of 30% or more, in an amount of 45% or more, in an amount of 60% or more, or

in an amount of 80% or more. The same applies to, for example, a rubber layer, an elastomer layer, an ethylene propylene rubber layer, a butyl rubber layer, a nitrile rubber layer, a natural rubber layer, a styrene-butadiene rubber layer, a silicone layer, an urethane layer, an acrylic resin layer, a metal layer, a resin film, and a ceramic film. The interposed layer 40 may be a blended layer including two or more materials.

[0022] The elastic modulus of the interposed layer 40 is, for example, 10000 N/m² to 20000000 N/m², and may be 20000 N/m² to 100000 N/m².

[0023] In an example, the pore diameter of the interposed layer 40 that is a porous body layer is 0.1 mm to 7.0 mm, and may be 0.3 mm to 5.0 mm. In another example, the pore diameter of the interposed layer 40 that is a porous body layer is, for example, 0.1 mm to 2.5 mm, and may be 0.2 mm to 1.5 mm or 0.3 mm to 0.7 mm. The porosity of the interposed layer 40 that is a porous body layer is, for example, 70% to 99%, and may be 80% to 99% or 90% to 95%.

[0024] A known foam (for example, the foam used in Patent Literature 2) can be used as the interposed layer 40 that is a foam layer. The interposed layer 40 that is a foam layer may have an open-cell structure, a closed-cell structure, or a semi-open-/semi-closed-cell structure. The term "open-cell structure" refers to a structure having an open cell rate of 100%. The term "closed-cell structure" refers to a structure having an open cell rate of 0%. The term "semi-open-/semi-closed-cell structure" refers to a structure having an open cell rate of greater than 0% and less than 100%. The open cell rate can be calculated, for example, using the following equation after a test in which a foam layer is sunk in water: open cell rate (%) = {(volume of absorbed water)/(volume of cell part)} × 100. In a specific example, the "volume of absorbed water" can be obtained by sinking and leaving a foam layer in water under a reduced pressure of -750 mmHg (1 mmHg being equal to approximately 133.322 Pa) for 3 minutes, measuring the mass of water having replaced the air in cells of the foam layer, and converting the mass of water in the cells into volume on the assumption that the density of water is 1.0 g/cm³. The term "volume of cell part" refers to a value calculated using the following equation: volume of cell part (cm³) = {(mass of foam layer)/(apparent density of foam layer)} - {(mass of foam layer)/(density of material)}. The term "density of material" refers to the density of a matrix (solid, or non-hollow, body) forming the foam layer.

[0025] The foaming factor (the ratio between the density before foaming and that after foaming) of the interposed layer 40 that is a foam layer is, for example, 5 to 40, and may be 10 to 40.

[0026] The interposed layer 40 in an uncompressed state has a thickness of, for example, 0.1 mm to 30 mm, and may have a thickness of 1 mm to 30 mm, 1.5 mm to 30 mm, or 2 mm to 25 mm. The interposed layer 40 in an uncompressed state is typically thicker than the piezoelectric film 35 in an uncompressed state. The thickness of the interposed layer 40 in an uncompressed state is, for example, 3 or more times the thickness of the piezoelectric film 35 in an uncompressed state, and may be 10 or more times or 30 or more times the thickness of the piezoelectric film 35 in an uncompressed state. The interposed layer 40 in an uncompressed state is typically thicker than the first pressure-sensitive adhesive layer 51 in an uncompressed state.

[0027] A surface of the first pressure-sensitive adhesive layer 51 forms the fixing face 17. The first pressure-sensitive adhesive layer 51 is a layer to be joined to a support. In the example in FIG. 1, the first pressure-sensitive adhesive layer 51 is joined to the interposed layer 40. Examples of the first pressure-sensitive adhesive layer 51 include a double-faced tape including a substrate and a pressure-sensitive adhesive applied to the both sides of the substrate. Examples of the substrate of the double-faced tape used as the first pressure-sensitive adhesive layer 51 include non-woven fabric. Examples of the pressure-sensitive adhesive of the double-faced tape used as the first pressure-sensitive adhesive layer 51 include pressure-sensitive adhesives including an acrylic resin. The first pressure-sensitive adhesive layer 51 may be a layer including no substrate and formed of a pressure-sensitive adhesive.

[0028] The thickness of the first pressure-sensitive adhesive layer 51 is, for example, 0.01 mm to 1.0 mm, and may be 0.05 mm to 0.5 mm.

[0029] The second pressure-sensitive adhesive layer 52 is disposed between the interposed layer 40 and the piezoelectric film 35. Specifically, the second pressure-sensitive adhesive layer 52 is joined to the interposed layer 40 and the piezoelectric film 35. Examples of the second pressure-sensitive adhesive layer 52 include a double-faced tape including a substrate and a pressure-sensitive adhesive applied to the both sides of the substrate. Examples of the substrate of the double-faced tape used as the second pressure-sensitive adhesive layer 52 include non-woven fabric. Examples of the pressure-sensitive adhesive of the double-faced tape used as the second pressure-sensitive adhesive layer 52 include pressure-sensitive adhesives including an acrylic resin. The second pressure-sensitive adhesive layer 52 may be a layer including no substrate and formed of a pressure-sensitive adhesive.

[0030] The thickness of the second pressure-sensitive adhesive layer 52 is, for example, 0.01 mm to 1.0 mm, and may be 0.05 mm to 0.5 mm.

[0031] In the present embodiment, the piezoelectric film 35 is integrated with the layers on the fixing face 17 side by bringing an adhesive face or a pressure-sensitive adhesive face into contact with the piezoelectric film 35. Specifically, in the present embodiment, the adhesive face or the pressure-sensitive adhesive face is a face formed of a surface of the second pressure-sensitive adhesive or adhesive layer 52.

[0032] In the present invention, the piezoelectric speaker 10 is applied to a sound reducing system 500 shown in FIG. 3. The sound reducing system 500 is a system including at least one sound reducing speaker for radiating a sound wave for

sound reduction. Specifically, a sound wave for sound reduction is a sound wave having, in a given region (a region where sound should be reduced) 300, an antiphase which is a phase opposite to that of a sound wave to be canceled out. The sound reducing system 500 further includes a reference microphone 130, a difference microphone 140, and a controller 110. Compared to a dynamic speaker, the piezoelectric speaker 10 requires a short time from arrival of a signal at the piezoelectric speaker 10 to emission of sound (the time may hereinafter be referred to as a delay time). Therefore, the piezoelectric speaker 10 is suitable for configuring a compact sound reducing system in that the piezoelectric speaker 10 not only is small but also can shorten the distance between the reference microphone 130 and the piezoelectric speaker 10. It is also possible, for example, to attach the reference microphone 130, the controller 110, and the piezoelectric speaker 10 to one partition.

[0033] In the sound reducing system 500, the at least one sound reducing speaker includes at least one piezoelectric speaker 10, and, in the present embodiment, includes a plurality of piezoelectric speakers 10. The sound reducing system 500 includes the support 80 supporting the piezoelectric speaker 35. The piezoelectric speaker 10 is fixed to the support 80. The fixing face 17 is in contact with the support 80. Including the plurality of piezoelectric speakers 10 is advantageous in view of sound reduction in a wide region.

[0034] In a state where the piezoelectric speaker 10 is fixed to the support 80, voltage is applied to the piezoelectric film 35 through the lead wires. This vibrates the piezoelectric film 35, and thus a sound wave is radiated from the piezoelectric film 35. In the example in FIG. 3, the support 80 has a flat surface, the piezoelectric speaker 10 is fixed to the flat surface, and the piezoelectric film 35 is extended flat thereon. This implementation is advantageous in that a sound wave radiated from the piezoelectric film 35 is close to a plane wave. When the support 80 has a curved surface, the piezoelectric speaker 10 may be fixed onto the curved surface.

[0035] As shown in FIG. 3, it is assumed that a sound wave to be canceled out arrives at a region 300 from a noise source 200 and has a waveform 290 in the region 300. The piezoelectric speaker 10 radiates a sound wave having, on the arrival at the region 300, a waveform 90 whose phase is opposite to that of the waveform 290. These sound waves cancel out each other in the region 300. In other words, a synthetic sound wave having a waveform 390 whose amplitude is reduced to 0 or a low level is generated by synthesis from these sound waves in the region 300. The sound reducing system 500 reduces sound in such a manner.

[0036] In a specific example, each of the plurality of piezoelectric speakers 10 forms a wave front. A synthetic wave front synthesized from the wave fronts of the piezoelectric speakers 10 propagates to the region 300. The propagation direction of the synthetic wave front can be controlled by controlling a phase difference between voltages applied to the piezoelectric speakers 10.

[0037] In the sound reducing system 500 shown in FIG. 3, feedforward control is performed using the reference microphone 130, the difference microphone 140, and the controller 110. Specifically, the reference microphone 130 detects a sound from the noise source 200. The reference microphone 130 is typically disposed on the noise source 200 side with respect to the piezoelectric speaker 10. Based on the sound detected by the reference microphone 130, the controller 110 adjusts a phase of a sound wave to be radiated from the piezoelectric speaker 10. The difference microphone 140 is disposed in the region 300 and detects sound in the region 300. Based on the sound detected by the difference microphone 140, the controller 110 adjusts the amplitude of a sound wave to be radiated from the piezoelectric speaker 10 to reduce the amplitude of the synthetic sound wave in the region 300.

[0038] A sound reducing system of a variant does not include the reference microphone 130. Feedback control is performed using the difference microphone 140 and the controller 110. Specifically, the difference microphone 140 adjusts the phase and the amplitude of a sound wave radiated from the piezoelectric speaker 10 to reduce the amplitude of a sound wave in the region 300. Consequently, in this case as well, a sound wave from the noise source 200 is canceled out in the region 300 by a sound wave having an antiphase and generated by the piezoelectric speaker 10.

[0039] In the sound reducing system 500 of the present embodiment, the support 80 is an article produced for a purpose other than supporting the piezoelectric film 35 and is used to support the piezoelectric film 35. Therefore, the sound reducing system 500 does not require a dedicated article for supporting the piezoelectric film 35. Such a system is advantageous in view of not narrowing a space. Specifically, in the present embodiment, the support 80 is a) a partition wall separating a room from outdoors or a different room, the separated room including a space where the sound reducing system 500 is to reduce sound or a space where the sound reducing system 500 is to prevent sound from escaping to an outside, b) a product installed in the separated room in an immovable or movable manner and having a function other than as a sound reducing speaker, c) a device or a tool designed to be capable of being carried or worn by a person, or d) a noise barrier installed outdoors.

[0040] Examples of the support 80 that is the above a) include a wall of a building, a ceiling, window glass, a vehicle body, a door, and a barrier defining a space containing a person. Examples of the support 80 that is the above b) include office furniture such as partitions, chairs, and tables, household electrical appliances, and sashes. Examples of the support 80 that is the above c) include helmets.

[0041] The area of a surface of the support 80, the surface facing the fixing face 17, is typically equal to or greater than the area of the fixing face 17. The former area is, for example, 1.0 or more times greater than the latter area, and may be 1.5 or

more times or 5 or more times greater than the latter area. The support 80 typically has a high stiffness (a product of Young's modulus and the second moment of area), a high Young's modulus, and/or a great thickness, compared to the interposed layer 40. The support 80 may have the same stiffness, Young's modulus, and/or thickness as that of the interposed layer 40, or may have a lower stiffness, a lower Young's modulus, and/or a smaller thickness than that of the interposed layer 40.

The support 80 has a Young's modulus of, for example, 1 GPa or more, and may have a Young's modulus of 10 GPa or more or 50 GPa or more. The upper limit of the Young's modulus of the support 80 is, for example, but not particularly limited to, 1000 GPa. Since various articles can be employed as the support 80, it is difficult to define the range of the thickness thereof. The thickness of the support 80 is, for example, 0.1 mm or more, and may be 1 mm or more, 10 mm or more, or 50 mm or more. The upper limit of thickness of the support 80 is, for example, but not particularly limited to, 1 m. The position and/or the shape of the support 80 typically does not vary depending on the piezoelectric speaker 10. The support 80 is typically produced on the assumption that the support 80 is not bent.

[0042] In an example, the sound reducing system 500 is used to reduce sound in a region where a person is. Specifically, the region 300 is a region where a person is. In another example, the sound reducing system 500 is used to prevent sound from escaping from the region where a person is. Specifically, the region where a person is is the noise source 200. The size of the region 300 is not particularly limited. In an example, the region 300 is a whole room, and in another example, the region 300 is a portion of a room.

[0043] The whole of the sound reducing system 500 according to the present embodiment and the components thereof will be further described.

[0044] In the sound reducing system 500, the film holding portion 55 is disposed between the piezoelectric film 35 and the support 80.

[0045] In the sound reducing system 500, (i) the film holding portion 55 includes a pressure-sensitive adhesive layer and the fixing face 17 is formed of a surface of the pressure-sensitive adhesive layer and (ii) the film holding portion 55 may include a porous body layer.

[0046] The sound reducing system 500 as described above is suitable for well radiating a sound wave for sound reduction from the piezoelectric film 35. The first pressure-sensitive adhesive layer 51 can fall under the pressure-sensitive adhesive layer in the above (i). The interposed layer 40 can fall under the porous body layer in the above (ii).

[0047] In the sound reducing system 500, the interposed layer 40 is disposed between the piezoelectric film 35 and the support 80.

[0048] It is likely that lower-frequency sound in the audible range is easily generated from the piezoelectric film 35 owing to the interposed layer 40 adequately holding one principal surface of the piezoelectric film 35, although the detail of the effect needs to be studied in the future. Given this, the interposed layer 40 can be disposed on a region accounting for 25% or more of the area of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan. The interposed layer 40 may be disposed on a region accounting for 50% or more of the area of the piezoelectric film 35, on a region accounting for 75% or more of the area of the piezoelectric film 35, or on the entire region of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan. 50% or more of a principal surface 15 of the piezoelectric speaker 10, the principal surface 15 being opposite to the fixing face 17, can be composed of the piezoelectric film 35. 75% or more of the principal surface 15 may be composed of the piezoelectric film 35. The entire principal surface 15 may be composed of the piezoelectric film 35.

[0049] In the present embodiment, the second pressure-sensitive adhesive layer 52 prevents separation of the piezoelectric film 35 and the interposed layer 40. In view of adequate holding, which is mentioned above, the second pressure-sensitive adhesive layer 52 and the interposed layer 40 can be disposed on a region accounting for 25% or more of the area of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan. The second pressure-sensitive adhesive layer 52 and the interposed layer 40 may be disposed on a region accounting for 50% or more of the area of the piezoelectric film 35, on a region accounting for 75% or more of the area of the piezoelectric film 35, or on the entire region of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan.

[0050] When the interposed layer 40 is a porous body, the rate of the region where the interposed layer 40 is disposed is not defined from a microscopical perspective in consideration of pores in the porous structure of the interposed layer 40, but rather from a relatively macroscopic perspective. For example, when the piezoelectric film 35, the interposed layer 40 that is a porous body, and the second pressure-sensitive adhesive layer 52 are plate-like bodies having the same outline in plan, the second pressure-sensitive adhesive layer 52 and the interposed layer 40 are described as being disposed on a region accounting for 100% of the area of the piezoelectric film 35.

[0051] In the present embodiment, the interposed layer 40 has a holding degree of $5 \times 10^9 \text{ N/m}^3$ or less. The interposed layer 40 has a holding degree of, for example, $1 \times 10^4 \text{ N/m}^3$ or more. The interposed layer 40 preferably has a holding degree of $5 \times 10^8 \text{ N/m}^3$ or less, more preferably $2 \times 10^8 \text{ N/m}^3$ or less, and even more preferably 1×10^5 to $5 \times 10^7 \text{ N/m}^3$. The holding degree (N/m^3) of the interposed layer 40 is a value obtained by dividing a product of the elastic modulus (N/m^2) of the interposed layer 40 and the surface filling factor of the interposed layer 40 by the thickness (m) of the interposed layer 40, as represented by the following equation. The surface filling factor of the interposed layer 40 is the filling factor (a value obtained by subtracting the porosity from 1) of the principal surface on the piezoelectric film 35 side of the interposed layer 40. When pores of the interposed layer 40 are evenly distributed, the surface filling factor can be regarded as equal to a

three-dimensionally determined filling factor of the interposed layer 40.

Holding degree (N/m^3) = Elastic modulus (N/m^2) $\times$ Surface filling factor $\div$ --> Thickness (m)

[0052] The holding degree can be considered to be a parameter representing the degree of holding the piezoelectric film 35 by means of the interposed layer 40. The above equation indicates that the greater the elastic modulus of the interposed layer 40 is, the greater the degree of holding becomes. The above equation indicates that the greater the surface filling factor of the interposed layer 40 is, the greater the degree of holding becomes. The above equation indicates that the smaller the thickness of the interposed layer 40 is, the greater the degree of holding becomes. Although the relationship between the holding degree of the interposed layer 40 and sound generated from the piezoelectric film 35 needs to be studied in the future, it is likely that an excessively great holding degree prevents the piezoelectric film 35 from deforming, which is necessary to emit lower-frequency sound. On the other hand, when the holding degree is excessively small, it is likely that the piezoelectric film 35 does not sufficiently deform in its thickness direction and extends and contracts only in its in-plane direction (the direction perpendicular to the thickness direction) and thus generation of lower-frequency sound is prevented. It is thought that since the holding degree of the interposed layer 40 is set within an adequate range, extension and contraction of the piezoelectric film 35 in the in-plane direction is adequately converted into deformation thereof in the thickness direction and that results in appropriate bending of the piezoelectric film 35 as a whole and makes it easy to generate lower-frequency sound.

[0053] The support 80 may have a greater holding degree than that of the interposed layer 40. In this case as well, lower-frequency sound can be generated from the piezoelectric film 35 because of the contribution of the interposed layer 40. The support 80 may have the same holding degree as that of the interposed layer 40, or may have a smaller holding degree than that of the interposed layer 40. The holding degree (N/m^3) of the support 80 is a value obtained by dividing a product of the elastic modulus (N/m^2) of the support 80 and the surface filling factor of the support 80 by the thickness (m) of the support 80. The surface filling factor of the support 80 is the filling factor (a value obtained by subtracting the porosity from 1) of the principal surface on the piezoelectric film 35 side of the support 80.

[0054] In the present embodiment, the fixing face 17 is disposed so that at least a portion of the piezoelectric film 35 overlaps the fixing face 17 (in the example in FIG. 1, overlaps the first pressure-sensitive adhesive layer 51) when the piezoelectric film 35 is viewed in plan. In view of stably fixing the piezoelectric speaker 10 to the support 80, the fixing face 17 can be disposed on a region accounting for 50% or more of the area of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan. The fixing face 17 may be disposed on a region accounting for 75% or more of the area of the piezoelectric film 35 or on the entire region of the piezoelectric film 35 when the piezoelectric film 35 is viewed in plan.

[0055] In the present embodiment, layers located between the piezoelectric film 35 and the fixing face 17 and adjacent to each other are joined together. The location between the piezoelectric film 35 and the fixing face 17 includes the piezoelectric film 35 and the fixing face 17. Specifically, the first pressure-sensitive adhesive layer 51 and the interposed layer 40 are joined together, the interposed layer 40 and the second pressure-sensitive adhesive layer 52 are joined together, and the second pressure-sensitive adhesive layer 52 and the piezoelectric film 35 are joined together. This allows the piezoelectric film 35 to be stably disposed regardless of the orientation in which the piezoelectric film 35 is attached to the support 80. This also makes it easy to attach the piezoelectric film 35 to the support 80. Moreover, because of the contribution of the interposed layer 40, sound is emitted from the piezoelectric film 35 regardless of the orientation in which the piezoelectric film 35 is attached. Thus, in the present embodiment, the combination of these allows achievement of a piezoelectric speaker of high usability. The expression "layers adjacent to each other are joined" means that layers adjacent to each other are entirely or partly joined together. In the illustrated example, the layers adjacent to each other are joined together in a given portion extending in the thickness direction of the piezoelectric film 35 in the order from the piezoelectric film 35, to the interposed layer 40, and to the fixing face 17.

[0056] In the present embodiment, the piezoelectric film 35 and the interposed layer 40 each have a substantially uniform thickness. This is often advantageous from various points of view, for example, in view of storage of the piezoelectric speaker 10, the usability thereof, and control of sound emitted from the piezoelectric film 35. Having a "substantially uniform thickness" refers to, for example, having the smallest thickness which is 70% or more and 100% or less of the largest thickness. The smallest thickness of each of the piezoelectric film 35 and the interposed layer 40 may be 85% or more and 100% or less of the largest thickness.

[0057] In the present embodiment, the piezoelectric film 35 and the film holding portion 55 each have a substantially uniform thickness. The piezoelectric film 35 and the film holding portion 55 may have the smallest thickness which is 85% or more and 100% or less of the largest thickness.

[0058] Resin is a material less likely to be cracked than, for example, ceramics. In a specific example, the piezoelectric body 30 of the piezoelectric film 35 is a resin film and the interposed layer 40 is a resin layer not functioning as a piezoelectric film. This specific example is advantageous in that the piezoelectric speaker 10 is cut, for example, with scissors or by hand without cracking the piezoelectric body 30 or the interposed layer 40 (the piezoelectric speaker 10 that

is cuttable, for example, with scissors or by hand contributes to greater design flexibility of the sound reducing system 500 and makes it easy to configure the sound reducing system 500). Additionally, in this specific example, the piezoelectric body 30 or the interposed layer 40 is unlikely to be cracked by bending the piezoelectric speaker 10. Moreover, that the piezoelectric body 30 is a resin film and the interposed layer 40 is a resin layer is advantageous in that the piezoelectric speaker 10 is fixed onto a curved surface without cracking the piezoelectric body 30 or the interposed layer 40.

[0059] In the example in FIG. 1, the piezoelectric film 35, the interposed layer 40, the first pressure-sensitive adhesive layer 51, and the second pressure-sensitive adhesive layer 52 each have the shape of a plate which is neither divided nor frame-shaped, and share the same outline when viewed in plan. Some or all of the piezoelectric film 35, the interposed layer 40, the first pressure-sensitive adhesive layer 51, and the second pressure-sensitive adhesive layer 52 may have the shape of a frame. Some or all thereof may be divided into two or more. Their outlines may be misaligned.

[0060] In the example in FIG. 1, the piezoelectric film 35, the interposed layer 40, the first pressure-sensitive adhesive layer 51, and the second pressure-sensitive adhesive layer 52 are each a rectangle having a short side and a long side when viewed in plan. The piezoelectric film 35, the interposed layer 40, the first pressure-sensitive adhesive layer 51, and the second pressure-sensitive adhesive layer 52 each may be, for example, a square, a circle, or an oval.

[0061] The piezoelectric speaker may also include a layer other than the layers shown in FIG. 1.

[0062] It goes without saying that the film holding portion 55 can be described as likely to include a layer which can be adopted as the interposed layer 40. This applies to a second embodiment described later. For example, the film holding portion 55 can be described as likely to include a resin layer not functioning as the piezoelectric film 35. The film holding portion 55 can be described as likely to include a porous body layer. The film holding portion 55 can be described as likely to include an ethylene propylene rubber foam layer.

[0063] Likewise, the film holding portion 55 can be described as likely to include a layer that can be adopted as the first pressure-sensitive adhesive layer 51. The film holding portion 55 can be described as likely to include a layer that can be adopted as the second pressure-sensitive adhesive layer 52. For example, the film holding portion 55 can be described as likely to include a pressure-sensitive adhesive layer or an adhesive layer.

[Second embodiment]

[0064] A piezoelectric speaker 110 according to the second embodiment will be described using FIG. 4. The features identical to those of the first embodiment may not be described hereinafter.

[0065] A piezoelectric speaker 110 includes the piezoelectric film 35, a fixing face 117, and a film holding portion 155. The fixing face 117 can be used to fix the piezoelectric film 35 to a support.

[0066] The film holding portion 155 is located between the piezoelectric film 35 and the fixing face 117. (The location between the piezoelectric film 35 and the fixing face 117 includes the fixing face 117. The same applies to the first embodiment.) In the example in FIG. 4, the film holding portion 155 is composed of an interposed layer 140. The fixing face 117 is formed of a surface (principal surface) of the interposed layer 140.

[0067] The interposed layer 140 is a porous body layer and/or a resin layer. The interposed layer 140 is a pressure-sensitive adhesive layer or an adhesive layer. A pressure-sensitive adhesive including an acrylic resin can be used as the interposed layer 140. Another pressure-sensitive adhesive, for example, a pressure-sensitive adhesive including rubber, silicone, or urethane may be used as the interposed layer 140. The interposed layer 140 may be a blended layer including two or more materials.

[0068] The elastic modulus of the interposed layer 140 is, for example, 10000 N/m^2 to 20000000 N/m^2 , and may be 20000 N/m^2 to 100000 N/m^2 .

[0069] The interposed layer 140 in an uncompressed state has a thickness of, for example, 0.1 mm to 30 mm, and may have a thickness of 1 mm to 30 mm, 1.5 mm to 30 mm, or 2 mm to 25 mm. The interposed layer 140 in an uncompressed state is typically thicker than the piezoelectric film 35 in an uncompressed state. The thickness of the interposed layer 140 in an uncompressed state is, for example, 3 or more times the thickness of the piezoelectric film 35 in an uncompressed state, and may be 10 or more times or 30 or more times the thickness of the piezoelectric film 35 in an uncompressed state.

[0070] In the present embodiment, the interposed layer 140 has a holding degree of $5 \times 10^9 \text{ N/m}^3$ or less. The interposed layer 140 has a holding degree of, for example, $1 \times 10^4 \text{ N/m}^3$ or more. The interposed layer 140 preferably has a holding degree of $5 \times 10^8 \text{ N/m}^3$ or less, more preferably $2 \times 10^8 \text{ N/m}^3$ or less, and even more preferably 1×10^5 to $5 \times 10^7 \text{ N/m}^3$. The definition of the holding degree is as described previously.

[0071] In the present embodiment, the piezoelectric film 35 is integrated with the layer on the fixing face 117 side by bringing an adhesive face or a pressure-sensitive adhesive face into contact with the piezoelectric film 35. Specifically, in the present embodiment, the adhesive face or the pressure-sensitive adhesive face is a face formed of the interposed layer 140.

[0072] The piezoelectric speaker 110 can also be fixed to the support 80 of FIG. 3 with the aid of the fixing face 117. The sound reducing system 500 employing the piezoelectric speaker 110 can be configured in such a manner.

[0073] In the sound reducing system 500, (i) the film holding portion 155 includes a pressure-sensitive adhesive layer

and the fixing face 117 is formed of a surface of the pressure-sensitive adhesive layer and (ii) the film holding portion 155 may include a porous body layer.

[0074] The sound reducing system 500 as described above is suitable for well radiating a sound wave for sound reduction from the piezoelectric film 35.

EXAMPLES

[0075] The present invention will be described in detail using Examples. It should be noted that Examples given below are only illustrative of the present invention and do not limit the present invention.

(Example 1)

[0076] A structure shown in FIG. 5 was produced by sticking a fixing face 17 of a piezoelectric speaker 10 to a supporting member 680 fixed. Specifically, a 5-mm-thick stainless steel plate (SUS plate) was used as the supporting member 680. A 0.16-mm-thick pressure-sensitive adhesive sheet (double-faced tape) including non-woven fabric both sides of which were impregnated with an acrylic adhesive was used as the first pressure-sensitive adhesive layer 51. A 3-mm-thick closed-cell foam obtained by foaming a mixture including ethylene propylene rubber and butyl rubber by a foaming factor of about 10 was used as the interposed layer 40. A 0.15-mm-thick pressure-sensitive adhesive sheet (double-faced tape) including non-woven fabric as a substrate to the both sides of which a pressure-sensitive adhesive including a solventless acrylic resin was applied was used as the second pressure-sensitive adhesive layer 52. A polyvinylidene fluoride film on each side of which a copper electrode (including nickel) was vapor-deposited (total thickness: 33 μ m) was used as the piezoelectric film 35. The first pressure-sensitive adhesive layer 51, the interposed layer 40, the second pressure-sensitive adhesive layer 52, and the piezoelectric film 35 of Example 1 each have dimensions of 37.5 mm long by 37.5 mm wide when viewed in plan, each have the shape of a plate which is neither divided nor frame-shaped, and have outlines overlapping when viewed in plan. (The same applies to Examples and Reference Example described later.) The supporting member 680 has dimensions of 50 mm long by 50 mm wide when viewed in plan and covers the entire first pressure-sensitive adhesive layer 51. A sample of Example 1 having the structure as shown in FIG. 5 was produced in this manner.

(Example 2)

[0077] A 3-mm-thick semi-open-/semi-closed-cell foam obtained by foaming a mixture including ethylene propylene rubber by a foaming factor of about 10 was used as an interposed layer 40. This foam includes sulfur. Except for that, a sample of Example 2 was produced in the same manner as in Example 1.

(Example 3)

[0078] A 5-mm-thick foam formed of the same material and having the same configuration as those of the interposed layer 40 of Example 2 was used as an interposed layer 40 in Example 3. Except for that, a sample of Example 3 was produced in the same manner as in Example 2.

(Example 4)

[0079] A 10-mm-thick foam formed of the same material and having the same configuration as those of the interposed layer 40 of Example 2 was used as an interposed layer 40 in Example 4. Except for that, a sample of Example 4 was produced in the same manner as in Example 2.

(Example 5)

[0080] A 20-mm-thick foam formed of the same material and having the same configuration as those of the interposed layer 40 of Example 2 was used as an interposed layer 40 in Example 5. Except for that, a sample of Example 5 was produced in the same manner as in Example 2.

(Example 6)

[0081] A 20-mm-thick semi-open-/semi-closed-cell foam obtained by foaming a mixture including ethylene propylene rubber by a foaming factor of about 10 was used as an interposed layer 40. This foam does not include sulfur and is more flexible than the foams used as the interposed layers 40 of Examples 2 to 5. Except for that, a sample of Example 6 was

produced in the same manner as in Example 1.

(Example 7)

5 **[0082]** A 20-mm-thick semi-open-/semi-closed-cell foam obtained by foaming a mixture including ethylene propylene rubber by a foaming factor of about 20 was used as an interposed layer 40. Except for that, a sample of Example 7 was produced in the same manner as in Example 1.

(Example 8)

10 **[0083]** A porous metal body was used as an interposed layer 40. This porous metal body is made of nickel and has a pore diameter of 0.9 mm and a thickness of 2.0 mm. A pressure-sensitive adhesive layer same as a first pressure-sensitive adhesive layer 51 as used in Example 1 was used as a second pressure-sensitive adhesive layer 52. Except for those, a sample of Example 8 was produced in the same manner as in Example 1.

15 (Example 9)

[0084] A first pressure-sensitive adhesive layer 51 and a second pressure-sensitive adhesive layer 52 as used in Example 1 were omitted, and only an interposed layer 140 was interposed between a piezoelectric film 35 as used in Example 1 and a support 80. A 3-mm-thick substrate-less pressure-sensitive adhesive sheet formed of an acrylic pressure-sensitive adhesive was used as the interposed layer 140. Except for those, a sample of Example 9 having a structure in which a laminate as in FIG. 5 is attached to a supporting member 680 as in FIG. 4 was produced in the same manner as in Example 1.

25 (Example 10)

[0085] An interposed layer same as an interposed layer 140 as used in Example 9 was used as an interposed layer 40. Except for that, a sample of Example 10 was produced in the same manner as in Example 8.

30 (Example 11)

[0086] A 5-mm-thick urethane foam was used as an interposed layer 40. Except for that, a sample of Example 11 was produced in the same manner as in Example 8.

35 (Example 12)

[0087] A 10-mm-thick urethane foam was used as an interposed layer 40. This urethane foam has a smaller pore diameter than that of the urethane foam used as the interposed layer 40 of Example 11. Except for that, a sample of Example 12 was produced in the same manner as in Example 8.

40 (Example 13)

[0088] A 5-mm-thick closed-cell acrylonitrile butadiene rubber foam was used as an interposed layer 40. Except for that, a sample of Example 13 was produced in the same manner as in Example 8.

45 (Example 14)

[0089] A 5-mm-thick closed-cell ethylene propylene rubber foam was used as an interposed layer 40. Except for that, a sample of Example 14 was produced in the same manner as in Example 8.

50 (Example 15)

[0090] A 5-mm-thick closed-cell foam in which natural rubber and styrene-butadiene rubber are blended was used as an interposed layer 40. Except for that, a sample of Example 15 was produced in the same manner as in Example 8.

55 (Example 16)

[0091] A 5-mm-thick closed-cell silicone foam was used as an interposed layer 40. Except for that, a sample of Example

16 was produced in the same manner as in Example 8.

(Example 17)

[0092] A 10-mm-thick foam formed of the same materials and having the same configuration as those of the interposed layer 40 of Example 1 was used as an interposed layer 40. A pressure-sensitive adhesive sheet same as the one used as the second pressure-sensitive adhesive layer 52 in Example 1 was used as the second pressure-sensitive adhesive layer 52. A 35- μm -thick resin sheet including a corn-derived polylactic acid as a main raw material was used as a piezoelectric body 30 of the piezoelectric film 35. A first electrode 61 and a second electrode 62 of the piezoelectric film 35 are each formed of a 0.1- μm -thick aluminum film and were formed by vapor deposition. A piezoelectric film 35 having a total thickness of 35.2 μm was thus obtained. Except for those, a sample of Example 17 was produced in the same manner as in Example 1.

(Reference Example 1)

[0093] A piezoelectric film 35 as used in Example 1 was employed as a sample of Reference Example 1. In Reference Example 1, the sample was placed on a board parallel to the ground without being adhered to the board.

[0094] The methods for evaluation of the samples according to Examples and Reference Example are as follows.

<Thickness of interposed layer (uncompressed state)>

[0095] The thickness of each of the interposed layers was measured using a thickness gauge.

<Elastic modulus of interposed layer>

[0096] A small piece was cut out from each of the interposed layers. The small piece was subjected to a compression test at ordinary temperature using a tensile tester ("RSA-G2" manufactured by TA Instruments). A stress-strain curve was thus obtained. The elastic modulus was calculated from the initial slope of the stress-strain curve.

<Pore diameter of interposed layer>

[0097] An enlarged image of each of the interposed layers was obtained using a microscope. The average of the pore diameters of the interposed layer was determined by image analysis of the enlarged image. The average thus determined was employed as the pore diameter of the interposed layer.

<Porosity of interposed layer>

[0098] A small rectangular cuboid piece was cut out from each of the interposed layers. The apparent density was determined from the volume and the mass of the small rectangular cuboid piece. The apparent density was divided by the density of a matrix (solid, or non-hollow, body) forming the interposed layer. The filling factor was thus calculated. Then, the filling factor was subtracted from 1. The porosity was thus obtained.

<Surface filling factor of interposed layer>

[0099] For Examples 2 to 16, the filling factor calculated as above is employed as the surface filling factor. For Examples 1 and 17, the surface filling factor is 100% because the interposed layers have a surface skin layer.

<Frequency characteristics of sample in terms of sound pressure level>

[0100] A structure for measurement of the samples of Examples 1 to 8 and 10 to 17 is shown in FIG. 6. An electrically conductive copper foil tape 70 (CU-35C manufactured by 3M) having dimensions of 70 μm thick by 5 mm long by 70 mm wide was attached to a corner of each side of the piezoelectric film 35. An alligator clip 75 with a cover was attached to each of the electrically conductive copper foil tapes 70. The electrically conductive copper foil tapes 70 and the alligator clips 75 with covers compose a portion of an electrical pathway used for application of AC voltage to the piezoelectric film 35.

[0101] A structure for measurement of the sample of Example 9 is shown in FIG. 7. The structure in FIG. 7 lacks the first pressure-sensitive adhesive layer 51 and the second pressure-sensitive adhesive layer 52 of FIG. 6. The structure in FIG. 7 includes the interposed layer 140.

[0102] A structure for measurement of the sample of Reference Example 1 is based on the structures of FIG. 6 and FIG.

7. Specifically, as in FIG. 6 and FIG. 7, an electrically conductive copper foil tape 70 was attached to a corner of each side of the piezoelectric film 35, and an alligator clip 75 with a cover was attached to each of the tapes 70. The resulting assembly was placed on a board parallel to the ground without being adhered to the board.

[0103] Block diagrams for measurement of the acoustic characteristics of the samples are shown in FIG. 8 and FIG. 9.

Specifically, an output system is shown in FIG. 8, and an evaluation system is shown in FIG. 9.

[0104] In the output system shown in FIG. 8, a personal computer (a personal computer may hereinafter be simply described as a PC) 401 for audio output, an audio interface 402, a speaker amplifier 403, a sample 404 (any of the piezoelectric speakers of Examples and Reference Example) were connected in this order. The speaker amplifier 403 was also connected to an oscilloscope 405 so that output from the speaker amplifier 403 to the sample 404 could be monitored.

[0105] WaveGene was installed in the PC 401 for audio output. WaveGene is free software for generation of a test audio signal. QUAD-CAPTURE manufactured by Roland Corporation was used as the audio interface 402. The sampling frequency of the audio interface 402 was set to 192 kHz. A-924 manufactured by Onkyo Corporation was used as the speaker amplifier 403. DPO2024 manufactured by Tektronix, Inc. was used as the oscilloscope 405.

[0106] In the evaluation system shown in FIG. 9, a microphone 501, an acoustic evaluation apparatus (PULSE) 502, and a PC 503 for acoustic evaluation were connected in this order.

[0107] Type 4939-C-002 manufactured by Briel & Kjaer Sound & Vibration Measurement A/S was used as the microphone 501. The microphone 501 was disposed 1 m away from the sample 404. Type 3052-A-030 manufactured by Briel & Kjaer Sound & Vibration Measurement A/S was used as the acoustic evaluation apparatus 502.

[0108] The output system and the evaluation system were configured in the above manners. AC voltage was applied from the PC 401 for audio output to the sample 404 via the audio interface 402 and the speaker amplifier 403. Specifically, a test audio signal whose frequency sweeps from 100 Hz to 100 kHz in 20 seconds was generated using the PC 401 for audio output. During this, voltage output from the speaker amplifier 403 was monitored using the oscilloscope 405. Additionally, sound generated from the sample 404 was evaluated using the evaluation system. A test for measurement of the sound pressure frequency characteristics was performed in this manner.

[0109] The details of the output system and evaluation system settings are as follows.

[Output system settings]

[0110]

- Frequency range: 100 Hz to 100 kHz
- Sweep time: 20 seconds
- Effective voltage: 10 V
- Output waveform: sine curve

[Evaluation system settings]

[0111]

- Measurement time: 22 seconds
- Peak hold
- Measurement range: 4 Hz to 102.4 kHz
- Number of lines: 6400

<Determination of frequency at which emission of sound starts>

[0112] The lower end of a frequency domain (exclusive of a sharp peak portion in which a frequency range where the sound pressure level is maintained higher than that of background noise by +3 dB or more falls within $\pm 10\%$ of a peak frequency (a frequency at which the sound pressure level reaches a peak)) where the sound pressure level is higher than that of background noise by 3 dB or more was determined as a frequency at which emission of sound starts.

[0113] The evaluation results for Examples 1 to 17 and Reference Example 1 are shown in FIG. 10A to FIG. 29. The frequency characteristics of background noise in terms of sound pressure level are shown in FIG. 30. E1 to E17 in FIG. 11 correspond to Examples 1 to 17.

[Piezoelectric film-supporting structure and degree of freedom of vibration]

[0114] FIG. 5 is referred back to for an exemplary piezoelectric speaker-supporting structure of the present invention. In the piezoelectric speaker 10, the entire surface of the piezoelectric film 35 is fixed to the support (supporting structure) 680

with the pressure-sensitive adhesive layers 51 and 52 and the interposed layer 40 therebetween.

[0115] It is also conceivable that a portion of the piezoelectric film 35 is supported to be spaced away from the support 680 in order to prevent the support 680 from hindering vibration of the piezoelectric film 35. An exemplary supporting structure based on this design concept is shown in FIG. 31. In a hypothetical piezoelectric speaker 108 shown in FIG. 31, a frame 88 supports a peripheral portion of the piezoelectric film 35 at a position distant from the support 680.

[0116] It is easy to ensure a sufficient volume of sound emitted from a piezoelectric film already curved and fixed in one direction. Therefore, it is conceivable that, for example, in the piezoelectric speaker 108, a nonuniformly thick interposition having a convex upper surface is disposed in a space 48 surrounded by the piezoelectric film 35, the frame 88, and the support 680 and a central portion of the piezoelectric film 35 is pushed upward. However, such an interposition is not joined to the piezoelectric film 35 so as not to hinder vibration of the piezoelectric film 35. Therefore, even with the interposition disposed in the space 48, it is only the frame 88 that supports the piezoelectric film 35 so as to determine vibration of the piezoelectric film 35.

[0117] As described above, the piezoelectric speaker 108 shown in FIG. 31 employs the supporting structure locally supporting the piezoelectric film 35. On the other hand, as shown in FIG. 5, the piezoelectric film 35 of the piezoelectric speaker 10 is not supported at a particular portion. Unexpectedly, the piezoelectric speaker 10 exhibits practical acoustic characteristics in spite of the fact that the entire surface of the piezoelectric film 35 is fixed to the support 80. Specifically, in the piezoelectric speaker 10, even a peripheral portion of the piezoelectric film 35 possibly vibrates up and down. The piezoelectric film 35 can vibrate up and down as a whole. Therefore, compared to the piezoelectric speaker 108, the piezoelectric speaker 10 has a higher degree of freedom of vibration and relatively advantageous in achieving good sound emission characteristics.

Claims

1. A sound reducing system (500) comprising at least one sound reducing speaker for radiating a sound wave for sound reduction, a support (80), a difference microphone (140), and a controller (110), wherein

the at least one sound reducing speaker comprises a piezoelectric speaker (10) which is supported by the support (80),

the piezoelectric speaker (10) comprises a piezoelectric film (35), a fixing face (17, 117) in contact with the support (80), and a film holding portion (55, 155) disposed between the piezoelectric film (35) and the fixing face (17, 117), the difference microphone (140) is configured to be disposed in a region (300) where sound should be reduced and to detect sound in the region (300), such that when a sound wave to be canceled out arrives at the region (300) from a noise source (200) and has a second waveform (290) in the region (300), a control is performed using the difference microphone (140) and the controller (110) so that the piezoelectric speaker (10) radiates a sound wave having, on the arrival at the region (300), a first waveform (90) whose phase is opposite to that of the waveform (290), **characterized in that**

the film holding portion (55, 155) comprises a first pressure-sensitive adhesive layer (51) and the fixing face (17, 117) is formed of a surface of the first pressure-sensitive adhesive layer (51),

the film holding portion (55, 155) comprises an interposed layer (40),

the film holding portion (55, 155) further comprises a second pressure-sensitive adhesive or second adhesive layer (52), and

the second pressure-sensitive adhesive or second adhesive layer (52) is disposed between the interposed layer (40) and the piezoelectric film (35).

2. The sound reducing system (500) according to claim 1, wherein the support (80) is

a) a partition wall separating a room from outdoors or a different room, the separated room including a space where the sound reducing system (500) is to reduce sound or a space where the sound reducing system (500) is to prevent sound from escaping to an outside,

b) a product installed in the separated room in an immovable or movable manner and having a function other than as a sound reducing speaker,

c) a device or a tool designed to be capable of being carried or worn by a person, or

d) a noise barrier installed outdoors.

3. The sound reducing system (500) according to claim 1 or 2, wherein

a piezoelectric body (30) of the piezoelectric film (35) is a resin film, and

the interposed layer (40) is a resin layer not functioning as a piezoelectric film.

4. The sound reducing system (500) according to any one of claims 1 to 3, wherein the smallest thickness of each of the piezoelectric film (35) and the film holding portion (55, 155) is 70% or more and 100% or less of the largest thickness.
5. The sound reducing system (500) according to any one of claims 1 to 4, wherein the interposed layer is a porous body layer.
6. The sound reducing system (500) according to claim 5, wherein the smallest thickness of each of the piezoelectric film (35) and the porous body layer is 70% or more and 100% or less of the largest thickness.
7. The sound reducing system (500) according to any one of claims 1 to 5, wherein 50% or more of a principal surface (15) of the piezoelectric speaker (10), the principal surface (15) being opposite to the fixing face (17, 117), is composed of the piezoelectric film (35).
8. The sound reducing system (500) according to any one of claims 1 to 7, wherein the fixing face (17, 117) is disposed in such a manner that at least a portion of the piezoelectric film (35) overlaps the fixing face (17, 117) when the piezoelectric film (35) is viewed in plan.
9. The sound reducing system (500) according to any one of claims 1 to 8, wherein the interposed layer is an ethylene propylene rubber foam layer.
10. The sound reducing system (500) according to any one of claims 1 to 9, wherein the first pressure-sensitive adhesive layer is joined to the interposed layer, the interposed layer is joined to the second pressure-sensitive adhesive or second adhesive layer, the second pressure-sensitive adhesive or second adhesive layer is joined to the piezoelectric film.
11. The sound reducing system (500) according to any one of claims 1 to 10, wherein the fixing face (17, 117) is disposed on a region accounting for 50% or more of an area of the piezoelectric film (35) when the piezoelectric film (35) is viewed in plan.
12. The sound reducing system (500) according to any one of claims 1 to 11, wherein the piezoelectric film (35) is extended flat.

Patentansprüche

1. Geräuschkämpfungssystem (500), umfassend mindestens einen geräuschkämpfenden Lautsprecher zum Abstrahlen einer Geräuschwelle zur Geräuschkämpfung, einen Träger (80), ein Differenzmikrofon (140) und eine Steuerung (110), wobei der mindestens eine geräuschkämpfende Lautsprecher einen piezoelektrischen Lautsprecher (10) umfasst, der von dem Träger (80) getragen wird, der piezoelektrische Lautsprecher (10) einen piezoelektrischen Film (35), eine Befestigungsfläche (17, 117) in Kontakt mit dem Träger (80) und einen Filmhalteabschnitt (55, 155), der zwischen dem piezoelektrischen Film (35) und der Befestigungsfläche (17, 117) angeordnet ist, umfasst, das Differenzmikrofon (140) konfiguriert ist, um in einem Bereich (300) angeordnet zu sein, in dem das Geräusch gedämpft werden soll, und um das Geräusch in dem Bereich (300) zu erfassen, sodass, wenn eine auszulöschende Geräuschwelle von einer Geräuschquelle (200) in dem Bereich (300) eintrifft und eine zweite Wellenform (290) in dem Bereich (300) aufweist, unter Verwendung des Differenzmikrofons (140) und der Steuerung (110) eine Steuerung durchgeführt wird, sodass der piezoelektrische Lautsprecher (10) eine Geräuschwelle abstrahlt, die bei der Ankunft in dem Bereich (300) eine erste Wellenform (90) aufweist, deren Phase derjenigen der Wellenform (290) entgegengesetzt ist, **dadurch gekennzeichnet, dass** der Filmhalteabschnitt (55, 155) eine erste Haftkleberschicht (51) umfasst und die Befestigungsfläche (17, 117) aus einer Oberfläche der ersten Haftkleberschicht (51) gebildet ist, der Filmhalteabschnitt (55, 155) eine eingefügte Schicht (40) umfasst,

der Filmhalteabschnitt (55, 155) ferner einen zweiten Haftkleber oder eine zweite Klebstoffschicht (52) umfasst, und
der zweite Haftkleber oder die zweite Klebstoffschicht (52) zwischen der eingefügten Schicht (40) und dem piezoelektrischen Film (35) angeordnet ist.

2. Geräuschdämpfungssystem (500) nach Anspruch 1, wobei der Träger (80)

- a) eine Trennwand ist, die einen Raum von der Außenwelt oder einem anderen Raum abtrennt, wobei der abgetrennte Raum einen Raum beinhaltet, in dem das Geräuschdämpfungssystem (500) das Geräusch dämpfen soll, oder einen Raum, in dem das Geräuschdämpfungssystem (500) verhindern soll, dass das Geräusch nach außen dringt,
- b) ein Produkt ist, das in dem abgetrennten Raum unbeweglich oder beweglich installiert ist und eine andere Funktion als die eines geräuschkämpfenden Lautsprechers aufweist,
- c) eine Vorrichtung oder ein Werkzeug ist, die/das in der Lage ist, um von einer Person mitgenommen oder getragen zu werden, oder
- d) eine im Freien installierte Lärmschutzwand ist.

3. Geräuschdämpfungssystem (500) nach Anspruch 1 oder 2, wobei

ein piezoelektrischer Körper (30) des piezoelektrischen Films (35) ein Harzfilm ist, und die eingefügte Schicht (40) eine Harzschicht ist, die nicht als piezoelektrischer Film funktioniert.

4. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 3, wobei die kleinste Stärke von jedem von dem piezoelektrischen Film (35) und dem Filmhalteabschnitt (55, 155) jeweils 70 % oder mehr und 100 % oder weniger der größten Stärke ist.

5. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 4, wobei die eingefügte Schicht eine poröse Körperschicht ist.

6. Geräuschdämpfungssystem (500) nach Anspruch 5, wobei die kleinste Stärke von jedem von dem piezoelektrischen Film (35) und der porösen Körperschicht jeweils 70 % oder mehr und 100 % oder weniger der größten Stärke ist.

7. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 5, wobei 50 % oder mehr einer Hauptoberfläche (15) des piezoelektrischen Lautsprechers (10), wobei die Hauptoberfläche (15) der Befestigungsfläche (17, 117) gegenüberliegt, aus dem piezoelektrischen Film (35) besteht.

8. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 7, wobei die Befestigungsfläche (17, 117) derart angeordnet ist, dass zumindest ein Abschnitt des piezoelektrischen Films (35) die Befestigungsfläche (17, 117) überlappt, bei Betrachten des piezoelektrischen Films (35) in der Draufsicht.

9. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 8, wobei die eingefügte Schicht eine Ethylen-Propylen-Kautschuk-Schaumschicht ist.

10. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 9, wobei

die erste druckempfindliche Klebstoffschicht mit der eingefügten Schicht verbunden ist, die eingefügte Schicht mit dem zweiten Haftkleber oder der zweiten Klebeschicht verbunden ist, der zweite Haftkleber oder die zweite Klebstoffschicht mit dem piezoelektrischen Film verbunden ist.

11. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 10, wobei die Befestigungsfläche (17, 117) in einem Bereich angeordnet ist, der 50 % oder mehr einer Fläche des piezoelektrischen Films (35) ausmacht, bei Betrachten des piezoelektrischen Films (35) in der Draufsicht.

12. Geräuschdämpfungssystem (500) nach einem der Ansprüche 1 bis 11, wobei der piezoelektrische Film (35) flach gestreckt ist.

Revendications

1. Système d'atténuation du son (500) comprenant au moins un haut-parleur à atténuation du son destiné à irradier une onde sonore en vue de l'atténuation du son, un support (80), un microphone différentiel (140) et un contrôleur (110), dans lequel

l'au moins un haut-parleur à atténuation du son comprend un haut-parleur piézoélectrique (10) qui est supporté par le support (80),

le haut-parleur piézoélectrique (10) comprend un film piézoélectrique (35), une face de fixation (17, 117) en contact avec le support (80), et une partie de maintien de film (55, 155) disposée entre le film piézoélectrique (35) et la face de fixation (17, 117),

le microphone différentiel (140) est configuré pour être disposé dans une zone (300) dans laquelle le son doit être atténué et pour détecter le son dans la zone (300), de sorte que, lorsqu'une onde sonore à neutraliser arrive au niveau de la zone (300) en provenance d'une source de bruit (200) et présente une deuxième forme d'onde (290) dans la zone (300), un contrôle soit effectué à l'aide du microphone différentiel (140) et du contrôleur (110) de sorte que le haut-parleur piézoélectrique (10) irradie une onde sonore ayant, à l'arrivée au niveau de la zone (300), une première forme d'onde (90) dont la phase est opposée à celle de la forme d'onde (290),

caractérisé en ce que

la partie de maintien de film (55, 155) comprend une première couche adhésive autocollante (51) et la face de fixation (17, 117) est formée d'une surface de la première couche adhésive autocollante (51),

la partie de maintien de film (55, 155) comprend une couche interposée (40),

la partie de maintien de film (55, 155) comprend en outre une deuxième couche adhésive autocollante ou une deuxième couche adhésive (52), et

la deuxième couche adhésive autocollante ou la deuxième couche adhésive (52) est disposée entre la couche interposée (40) et le film piézoélectrique (35).

2. Système d'atténuation du son (500) selon la revendication 1, dans lequel le support (80) est

a) une paroi de séparation qui sépare une pièce de l'extérieur ou d'une pièce différente, la pièce séparée comprenant un espace dans lequel le système d'atténuation du son (500) doit atténuer le son ou un espace dans lequel le système d'atténuation du son (500) doit empêcher le son de s'échapper vers un extérieur,

b) un produit installé dans la pièce séparée de manière immobile ou mobile et ayant une fonction autre que celle d'un haut-parleur à atténuation du son,

c) un dispositif ou un outil conçu pour pouvoir être porté par une personne, ou

d) un écran anti-bruit installé en extérieur.

3. Système d'atténuation du son (500) selon la revendication 1 ou 2, dans lequel un corps piézoélectrique (30) du film piézoélectrique (35) est un film de résine, et la couche interposée (40) est une couche de résine qui ne fonctionne pas comme un film piézoélectrique.

4. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 3, dans lequel la plus fine épaisseur de chacun du film piézoélectrique (35) et de la partie de maintien de film (55, 155) est égale à 70 % ou plus et 100 % ou moins de la plus grande épaisseur.

5. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 4, dans lequel la couche interposée est une couche de corps poreux.

6. Système d'atténuation du son (500) selon la revendication 5, dans lequel la plus fine épaisseur de chacun du film piézoélectrique (35) et de la couche de corps poreux est égale à 70 % ou plus et 100 % ou moins de la plus grande épaisseur.

7. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 5, dans lequel 50 % ou plus d'une surface principale (15) du haut-parleur piézoélectrique (10), la surface principale (15) étant opposée à la face de fixation (17, 117), sont composés du film piézoélectrique (35).

8. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 7, dans lequel la face de fixation (17, 117) est disposée de sorte qu'au moins une partie du film piézoélectrique (35) chevauche la face de fixation (17, 117) lorsque le film piézoélectrique (35) est vu de dessus.

9. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 8, dans lequel la couche interposée est une couche de mousse de caoutchouc éthylène-propylène.

10. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 9, dans lequel

la première couche adhésive autocollante est jointe à la couche interposée,
la couche interposée est jointe à la deuxième couche adhésive autocollante ou à la deuxième couche adhésive,
la deuxième couche adhésive autocollante ou la deuxième couche adhésive est jointe au film piézoélectrique.

11. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 10, dans lequel la face de fixation (17, 117) est disposée sur une zone qui représente 50 % ou plus d'une surface du film piézoélectrique (35) lorsque le film piézoélectrique (35) est vu de dessus.

12. Système d'atténuation du son (500) selon l'une quelconque des revendications 1 à 11, dans lequel le film piézoélectrique (35) est étiré à plat.

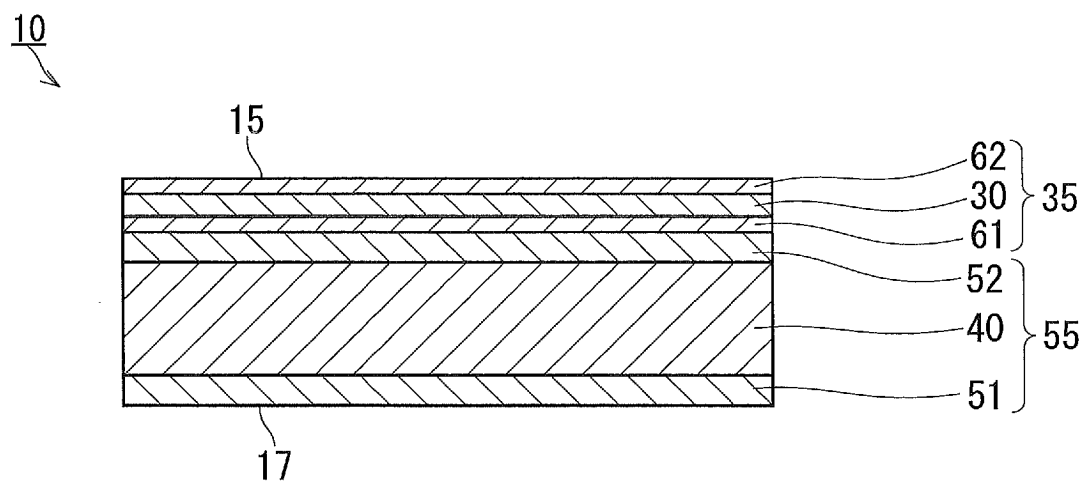


FIG.1

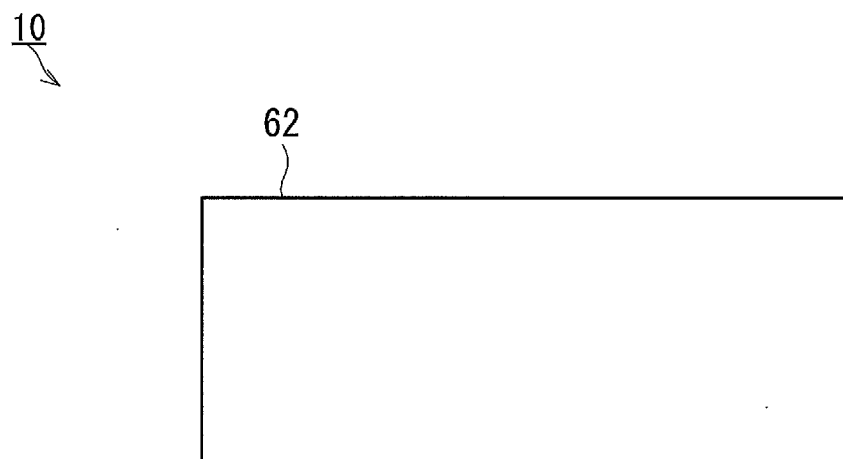


FIG.2

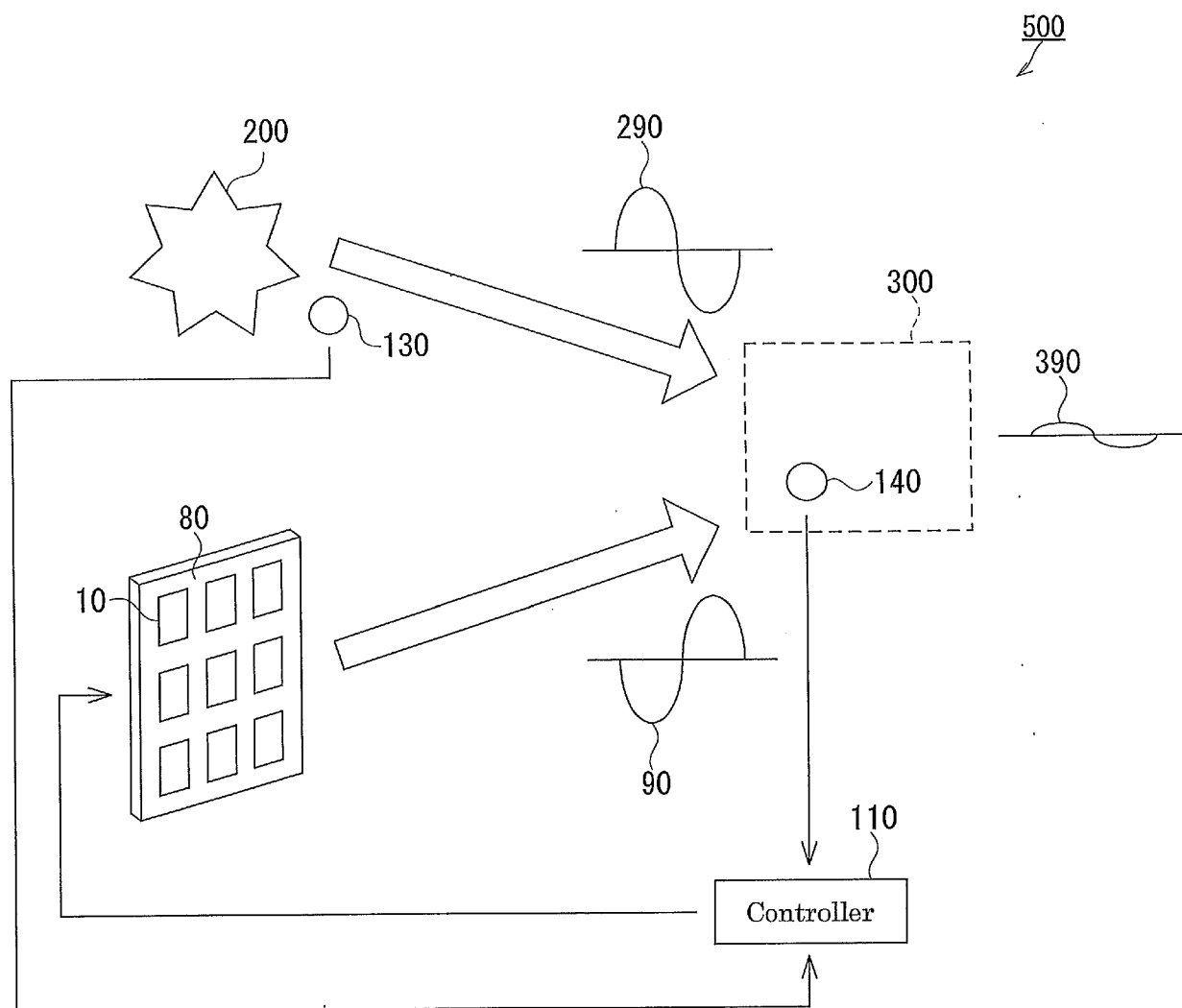


FIG.3

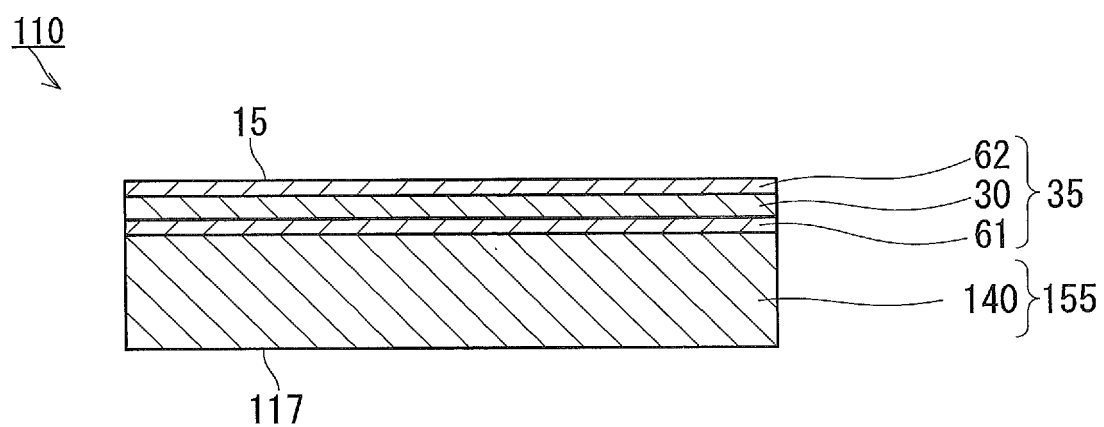


FIG.4

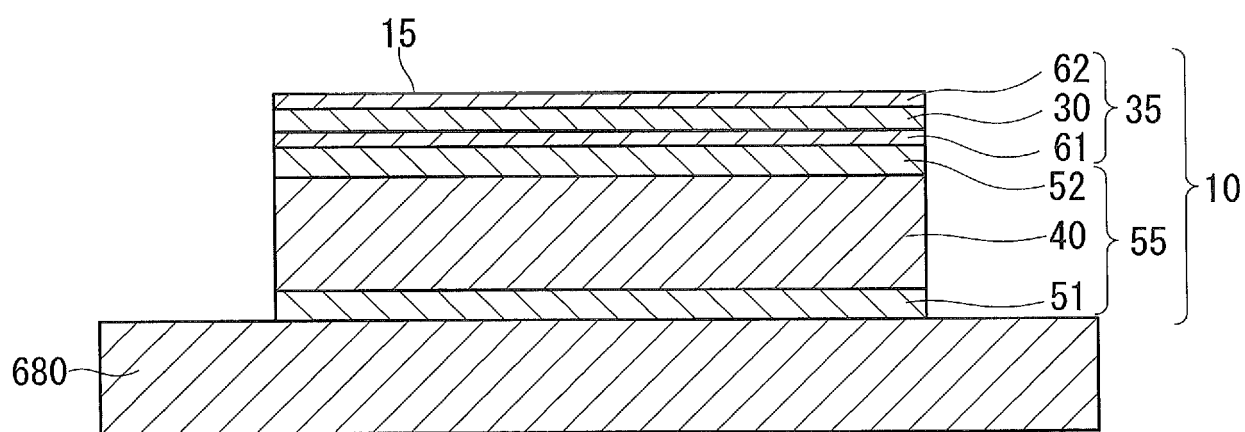


FIG.5

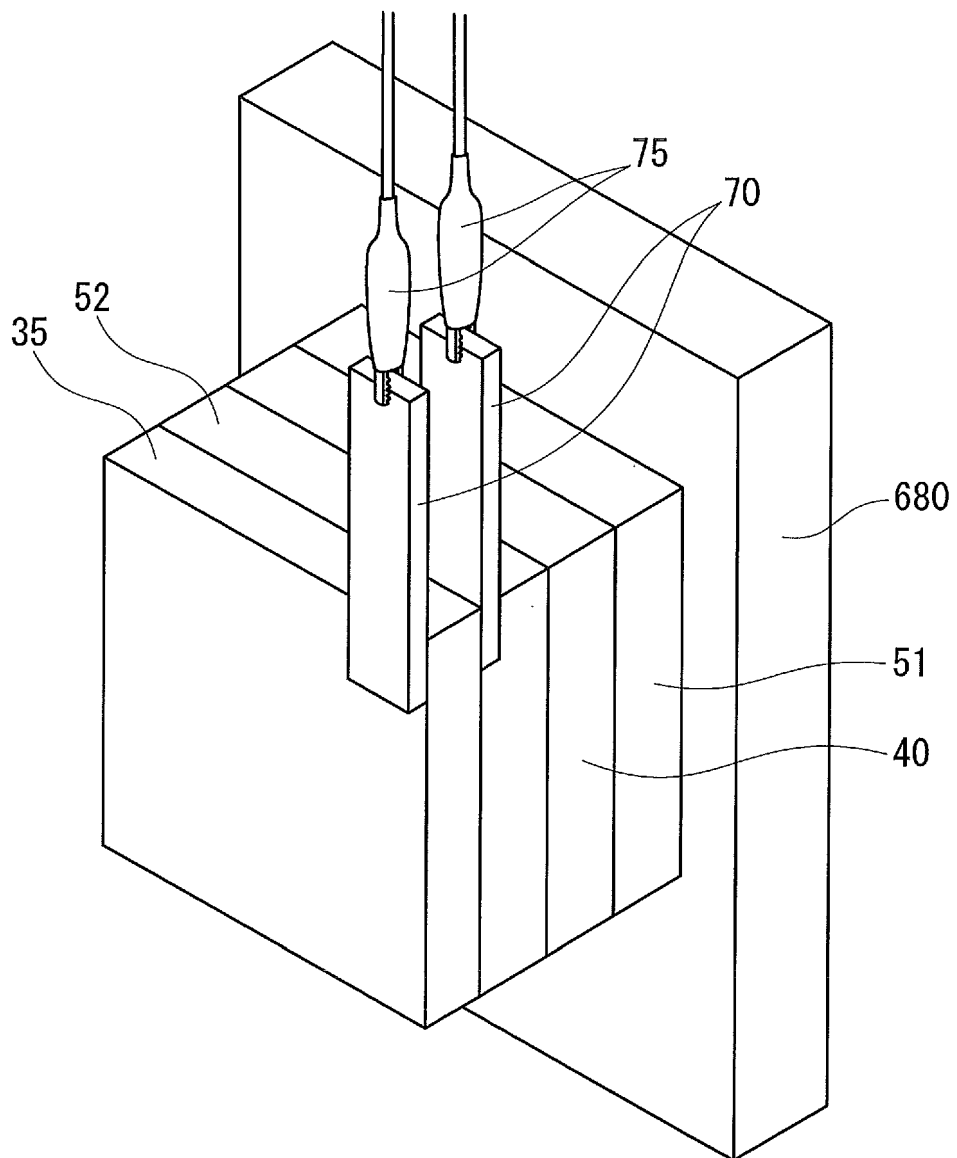


FIG.6

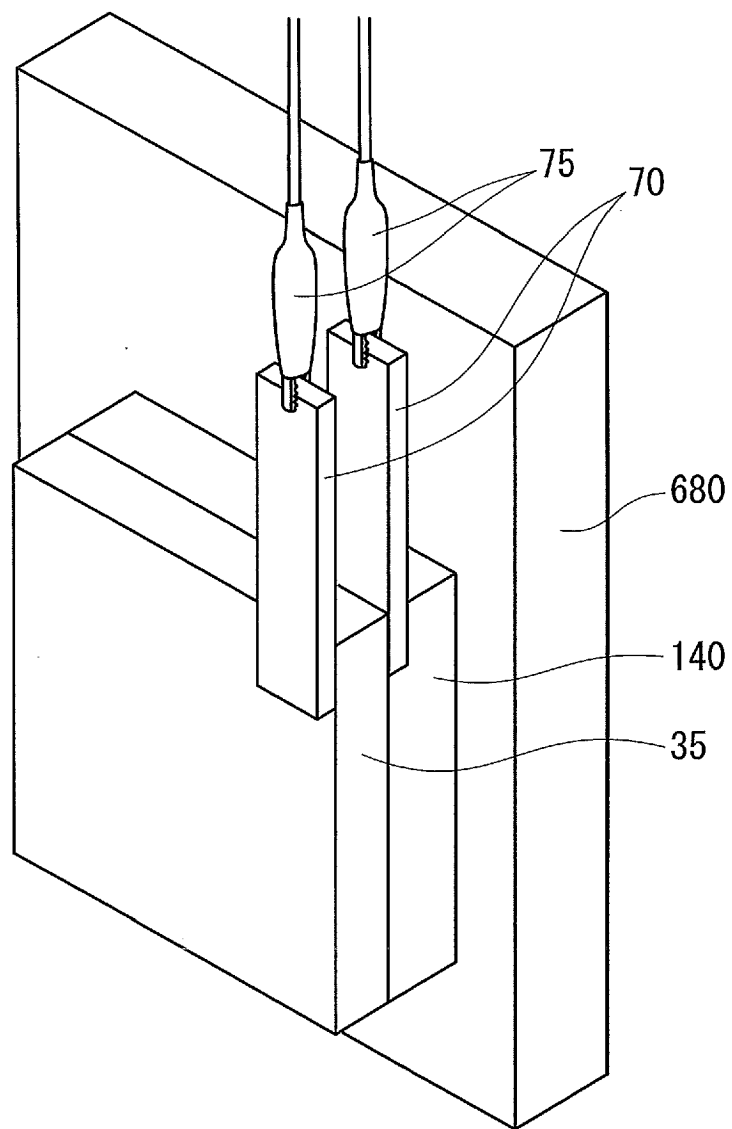


FIG. 7

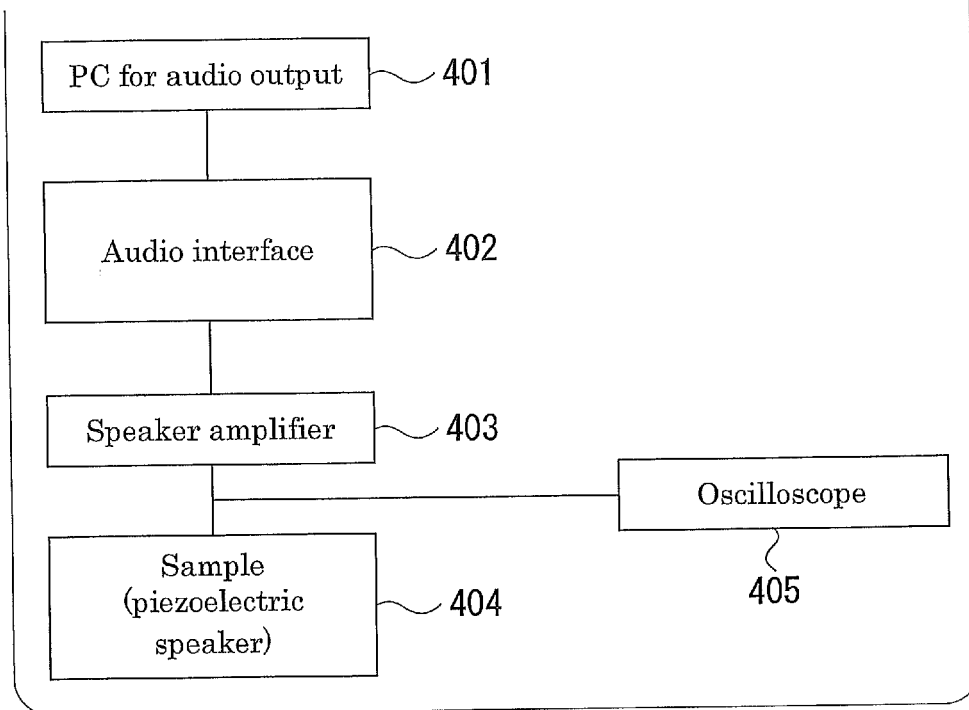
Output system

FIG.8

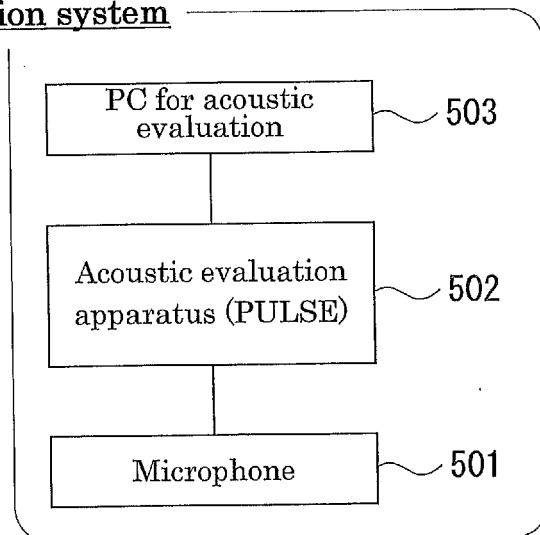
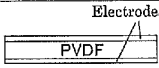
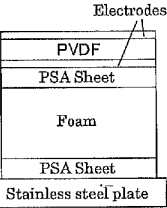
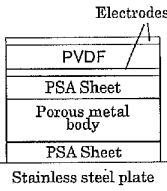
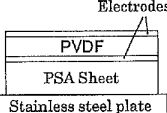
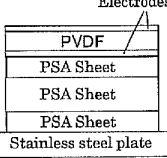
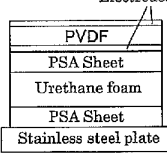
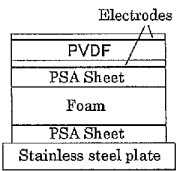
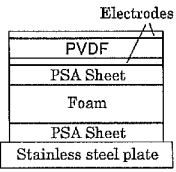
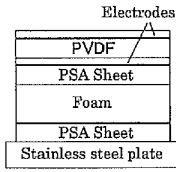
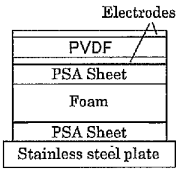
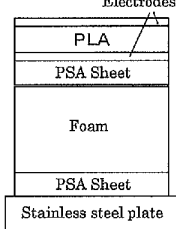
Evaluation system

FIG.9

	Overall structure	Type of interposed layer	Thickness (mm) of interposed layer	Elastic modulus E (N/m ²) of interposed layer	Structure of pores of interposed layer	Pore diameter (μm) of interposed layer	Porosity of interposed layer	Surface filling factor of interposed layer	Holding degree (N/m ²)	Frequency (Hz) at which emission of sound starts
Reference Example 1		-	-	-	-	-	-	-	0	3,500
Example 1		Foam	3	9.4E+04	Closed-cell	0.5	0.90	1.00	3.12E+07	3,300
Example 2		Foam	3	6.5E+04	Semi-open/semi-closed-cell	0.5	0.90	0.10	2.17E+06	2,400
Example 3		Foam	5	6.5E+04	Semi-open/semi-closed-cell	0.5	0.90	0.10	1.30E+06	2,100
Example 4		Foam	10	6.5E+04	Semi-open/semi-closed-cell	0.5	0.90	0.10	6.51E+05	1,400
Example 5		Foam	20	6.5E+04	Semi-open/semi-closed-cell	0.5	0.90	0.10	3.25E+05	2,000
Example 6		Foam	20	2.1E+04	Semi-open/semi-closed-cell	0.5	0.90	0.10	1.05E+05	3,000
Example 7		Foam	20	1.1E+04	Semi-open/semi-closed-cell	0.5	0.95	0.05	2.83E+04	4,000
Example 8		Porous metal body	2	3.0E+06	Open-cell	0.9	0.95	0.05	7.62E+07	4,000
Example 9		Pressure-sensitive adhesive sheet	3	2.5E+05	Non-porous	-	0.00	1.00	8.19E+07	4,000
Example 10		Pressure-sensitive adhesive sheet	3	2.5E+05	Non-porous	-	0.00	1.00	8.19E+07	6,000
Example 11		Urethane foam	5	2.0E+04	Open-cell	1.5	0.96	0.04	1.46E+05	3,000
Example 12		Urethane foam	10	1.6E+05	Open-cell	0.5	0.98	0.02	3.24E+05	2,500

※PSA: Pressure-sensitive adhesive

FIG.10A

	Overall structure	Type of interposed layer	Thickness (mm) of interposed layer	Elastic modulus E (N/m ²) of interposed layer	Structure of pores of interposed layer	Pore diameter (mm) of interposed layer	Porosity of interposed layer	Surface filling factor of interposed layer	Holding degree (N/m ²)	Frequency (Hz) at which emission of sound starts
Example 13		Foam	5	1.1E+05	Closed-cell	0.4	0.88	0.12	2.82E+06	2,300
Example 14		Foam	5	8.6E+04	Closed-cell	0.3	0.86	0.14	2.45E+06	2,400
Example 15		Foam	5	1.2E+05	Closed-cell	0.3	0.79	0.21	5.17E+06	2,500
Example 16		Foam	5	3.9E+04	Closed-cell	0.6	0.80	0.20	1.54E+06	1,800
Example 17		Foam	10	9.4E+04	Closed-cell	0.5	0.90	1.00	9.35E+06	2,200

※PSA:Pressure-sensitive adhesive

FIG.10B

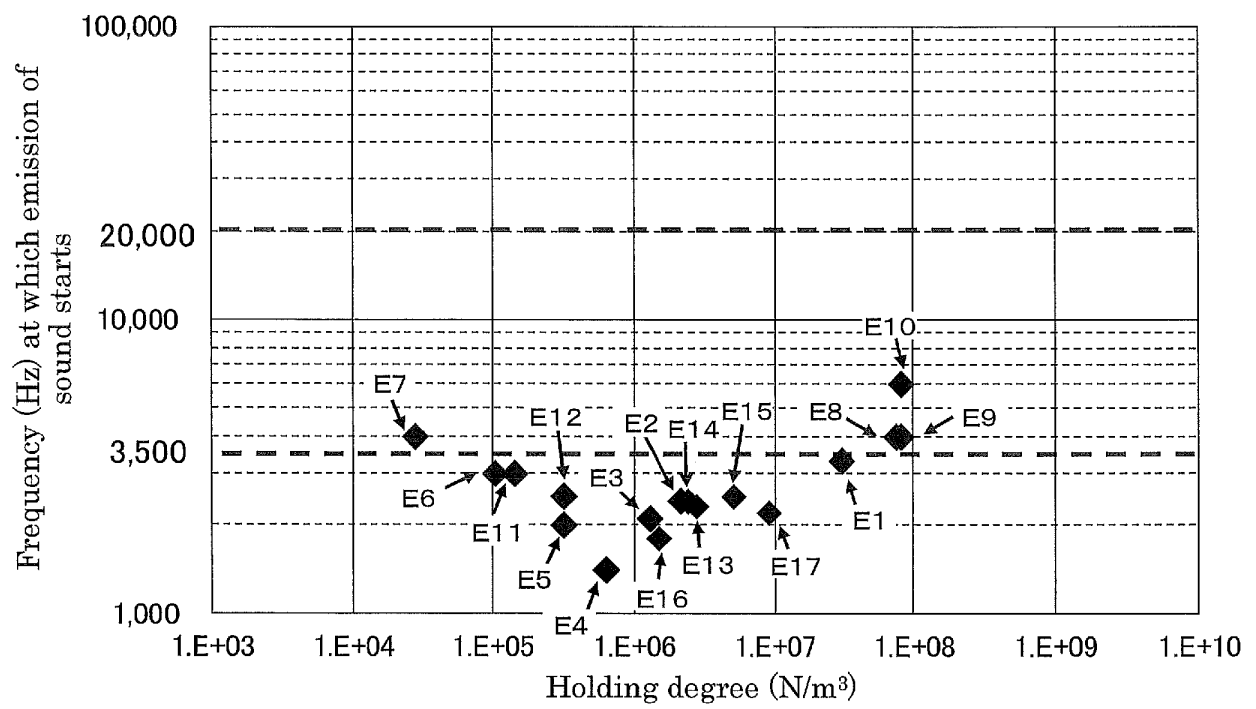


FIG.11

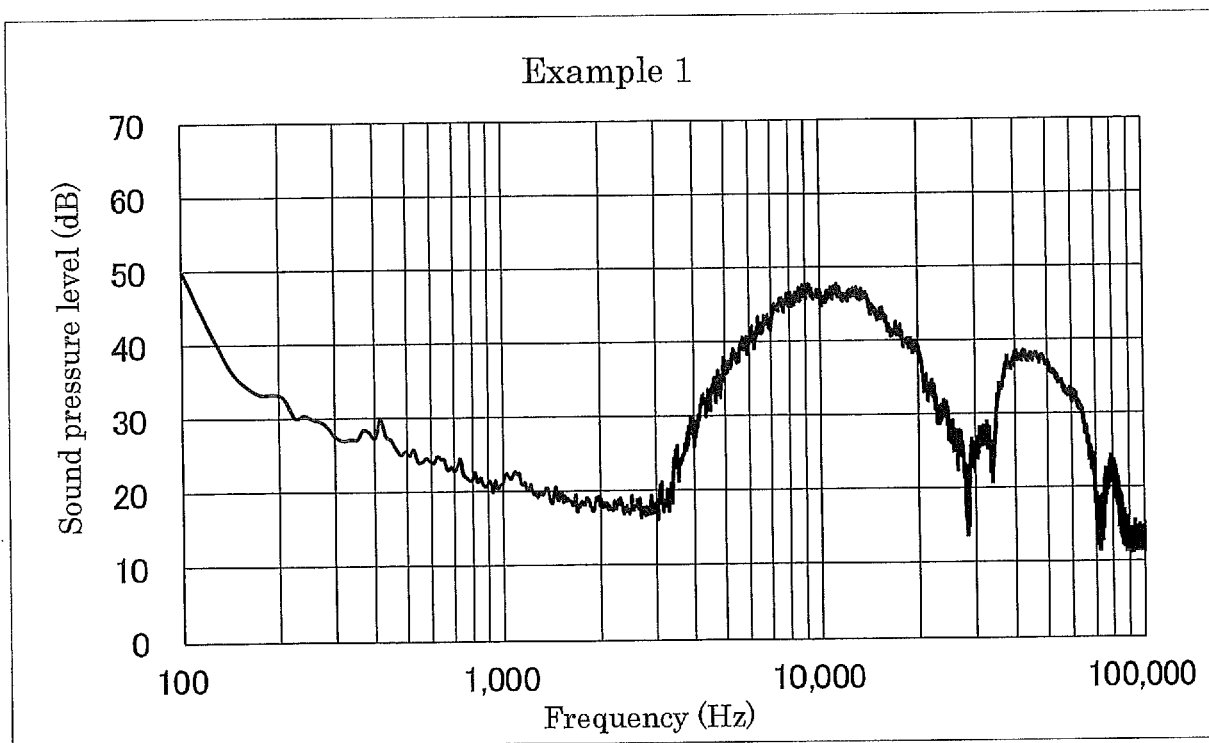


FIG.12

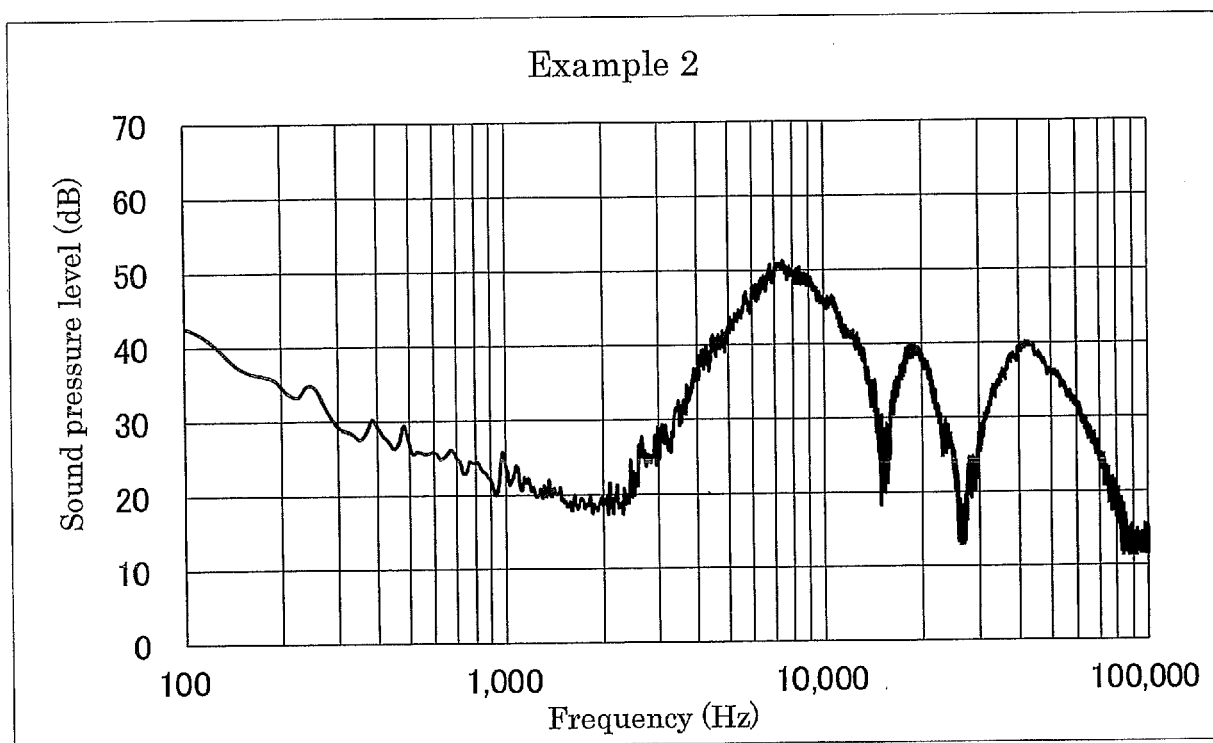
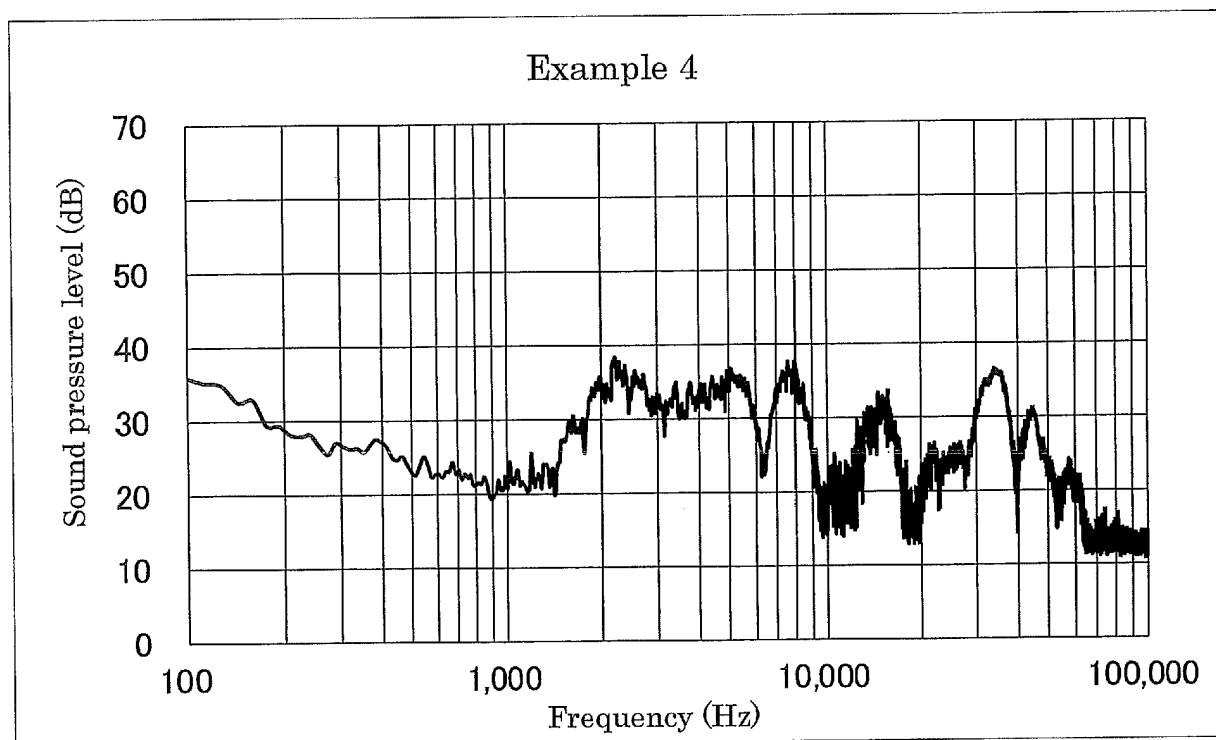
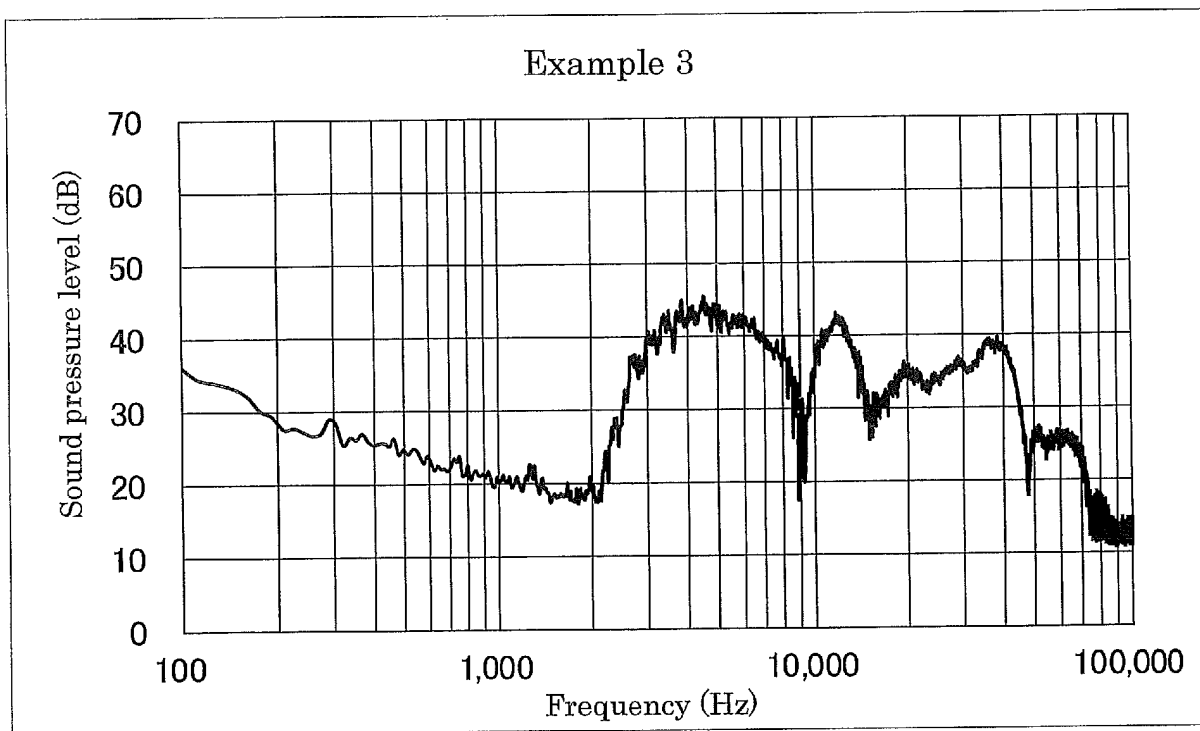


FIG.13



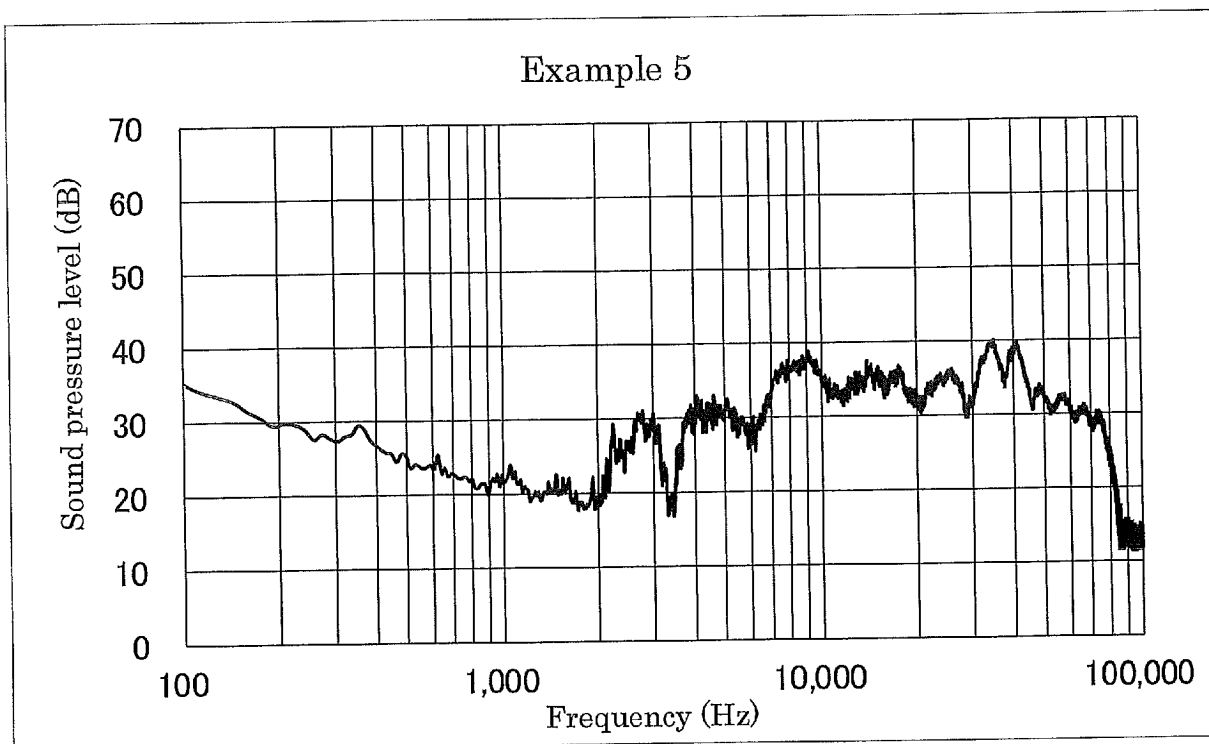


FIG.16

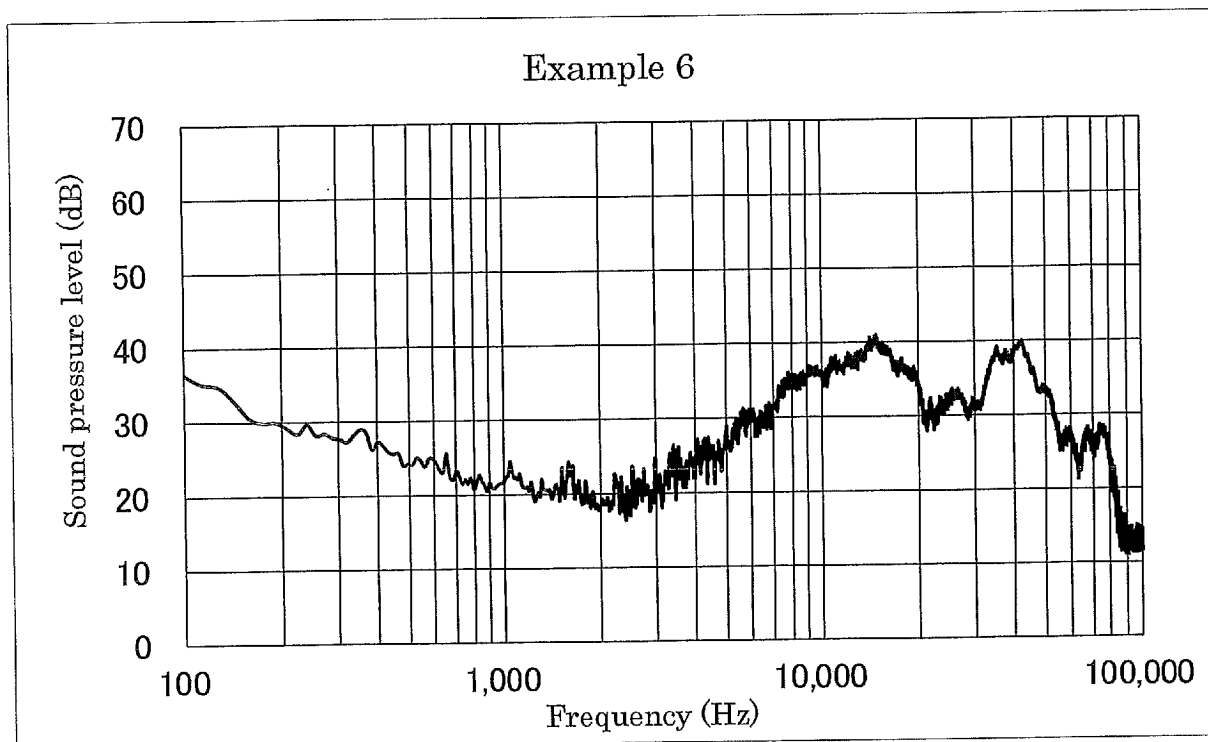
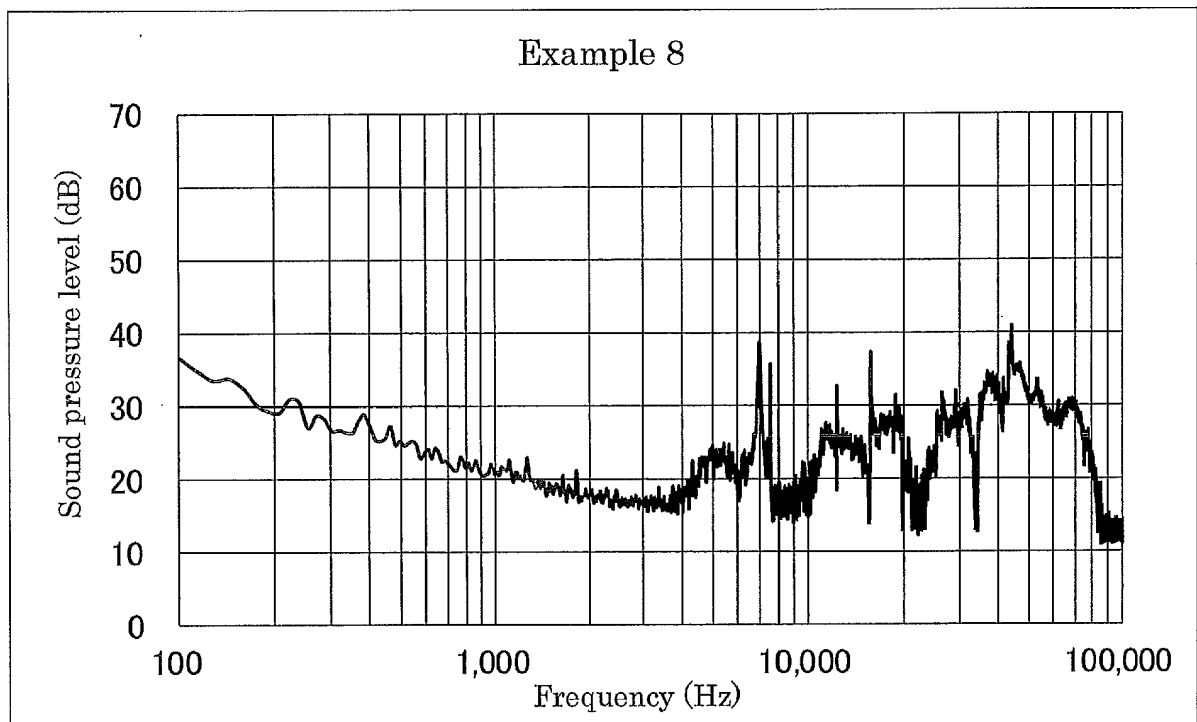
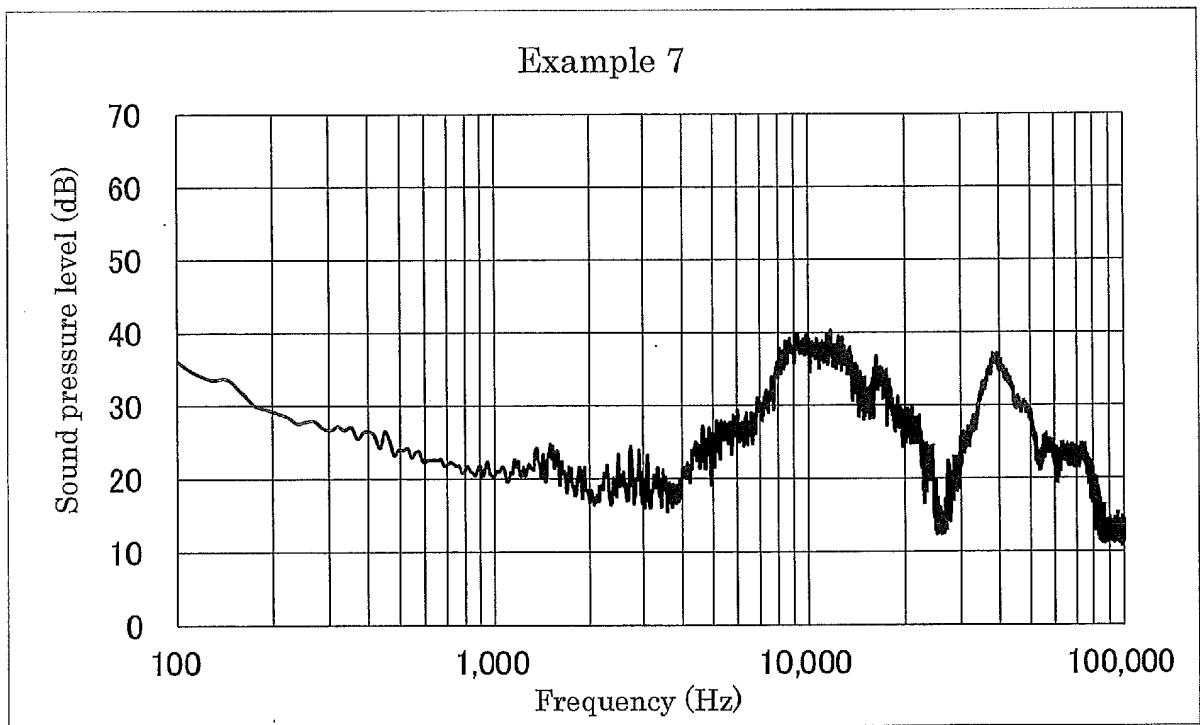


FIG.17



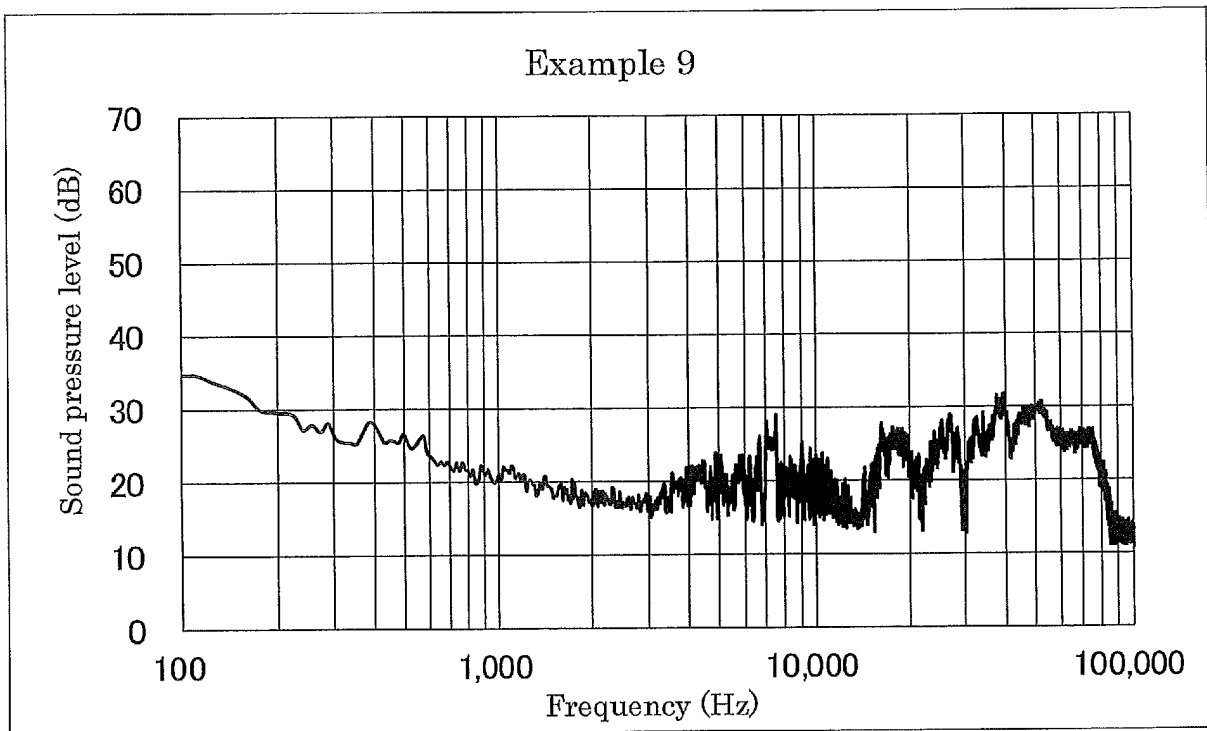


FIG.20

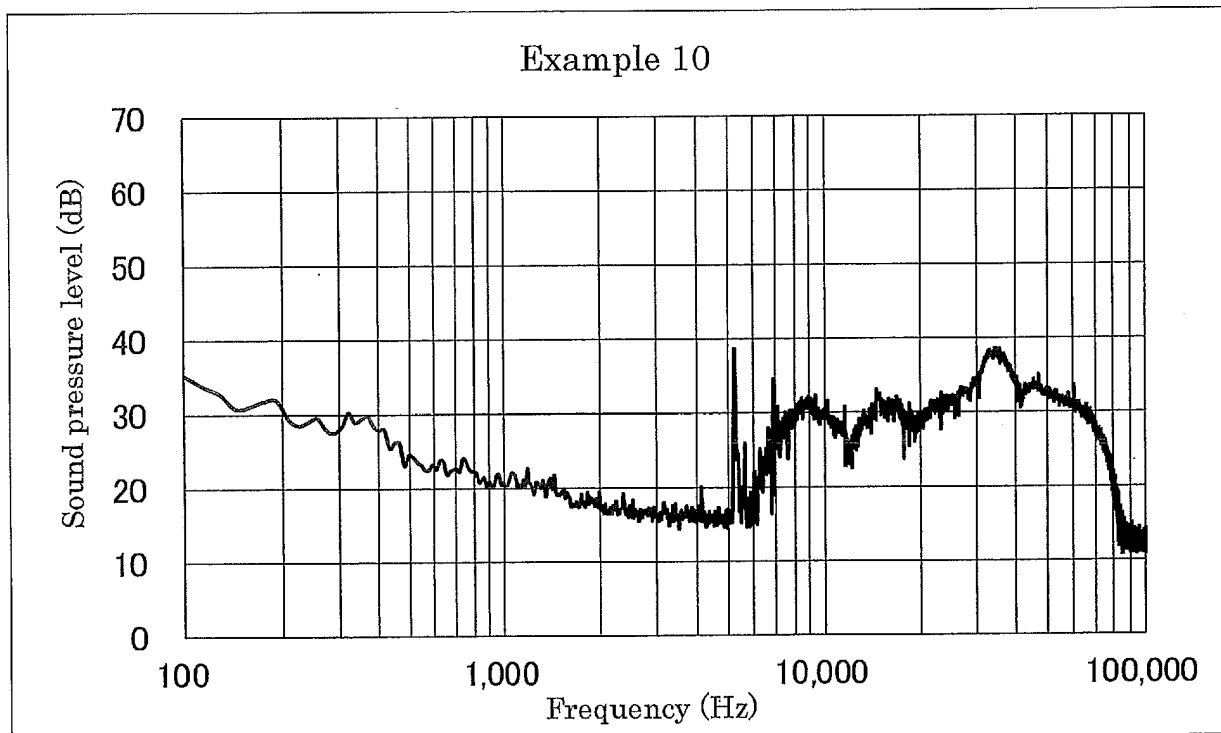


FIG.21

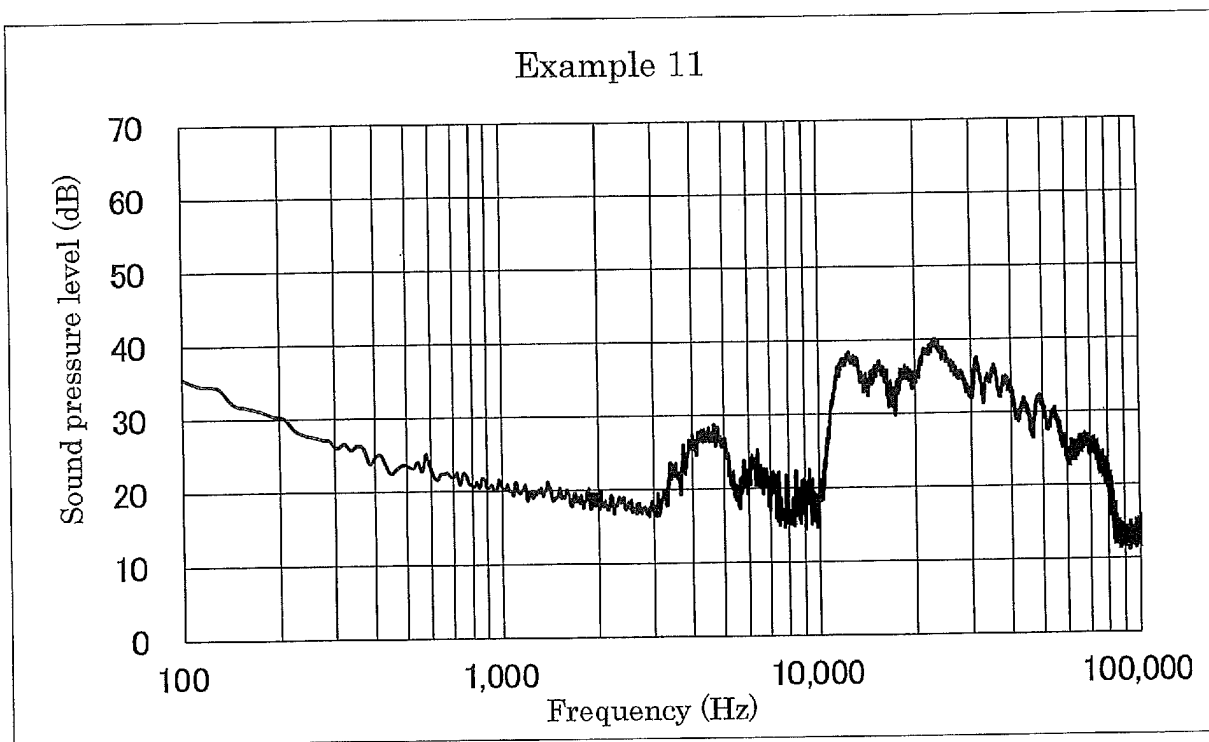


FIG.22

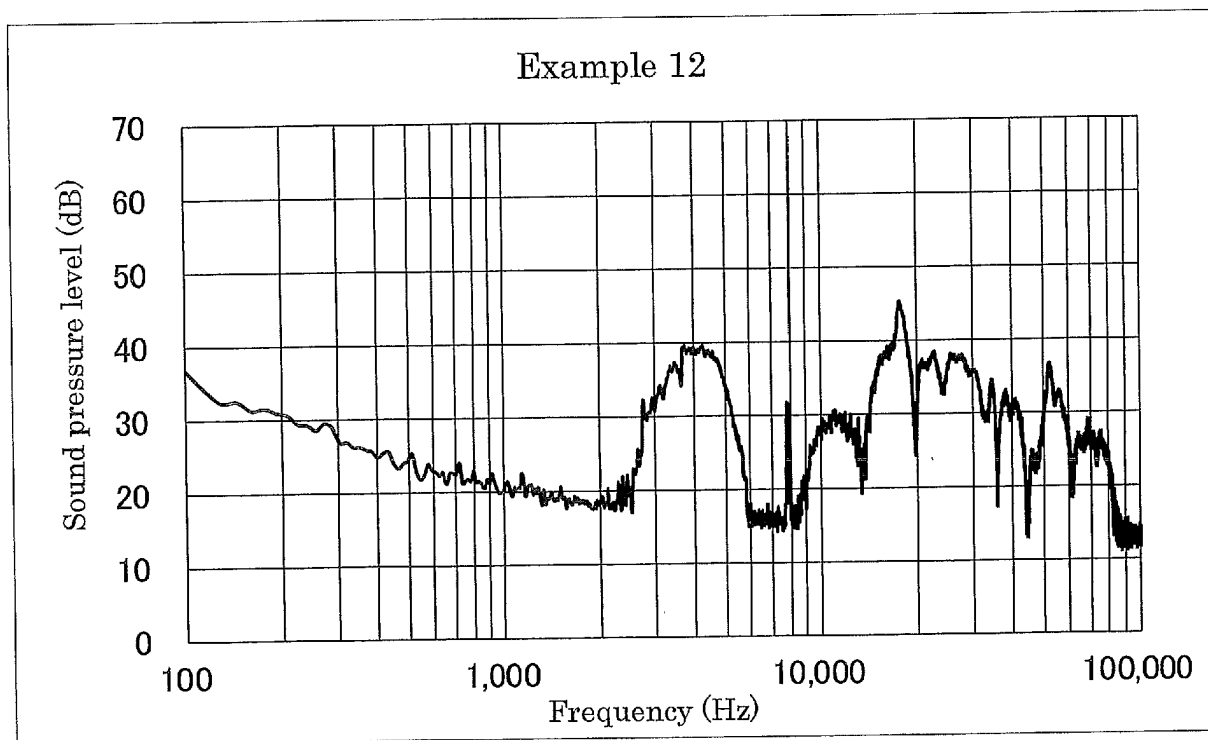


FIG.23

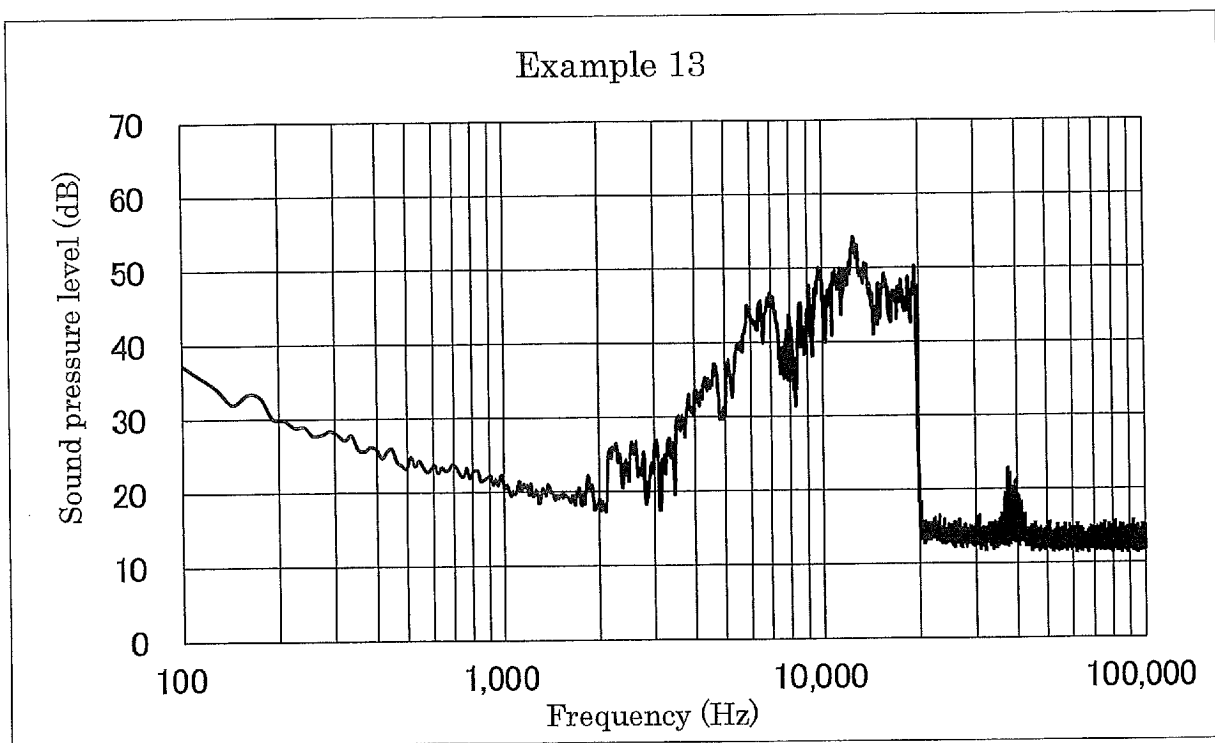


FIG.24

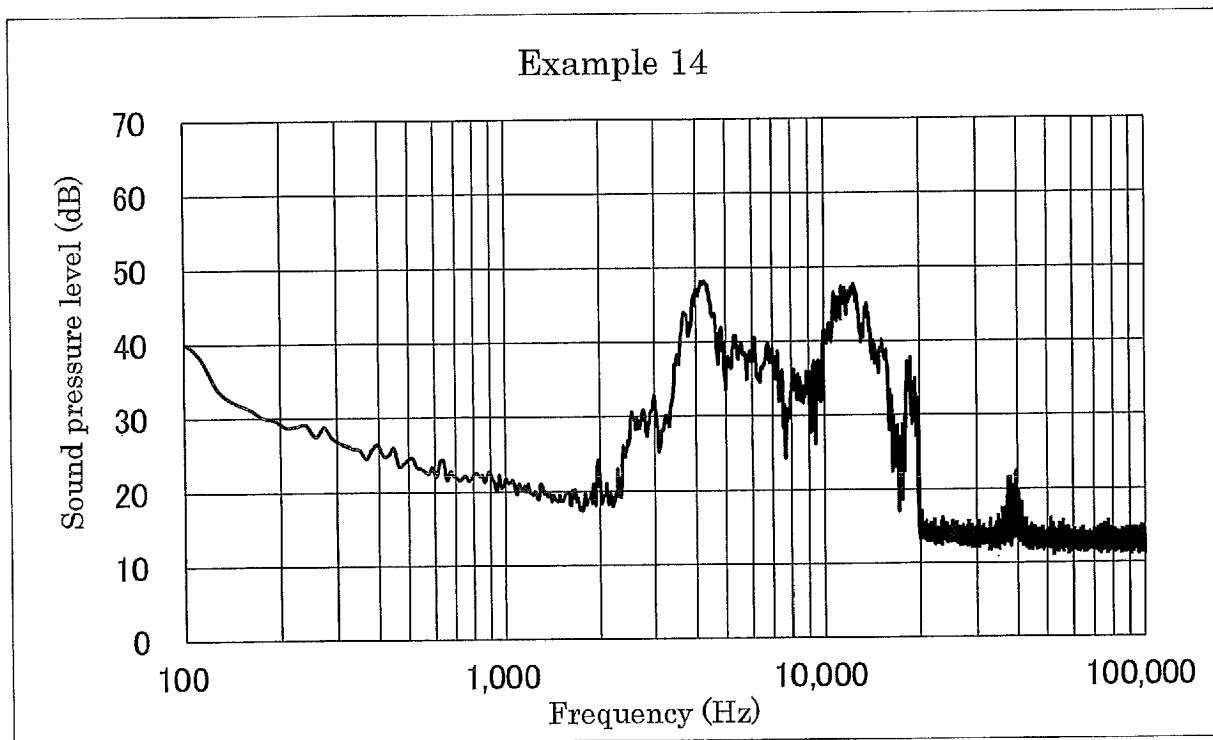


FIG.25

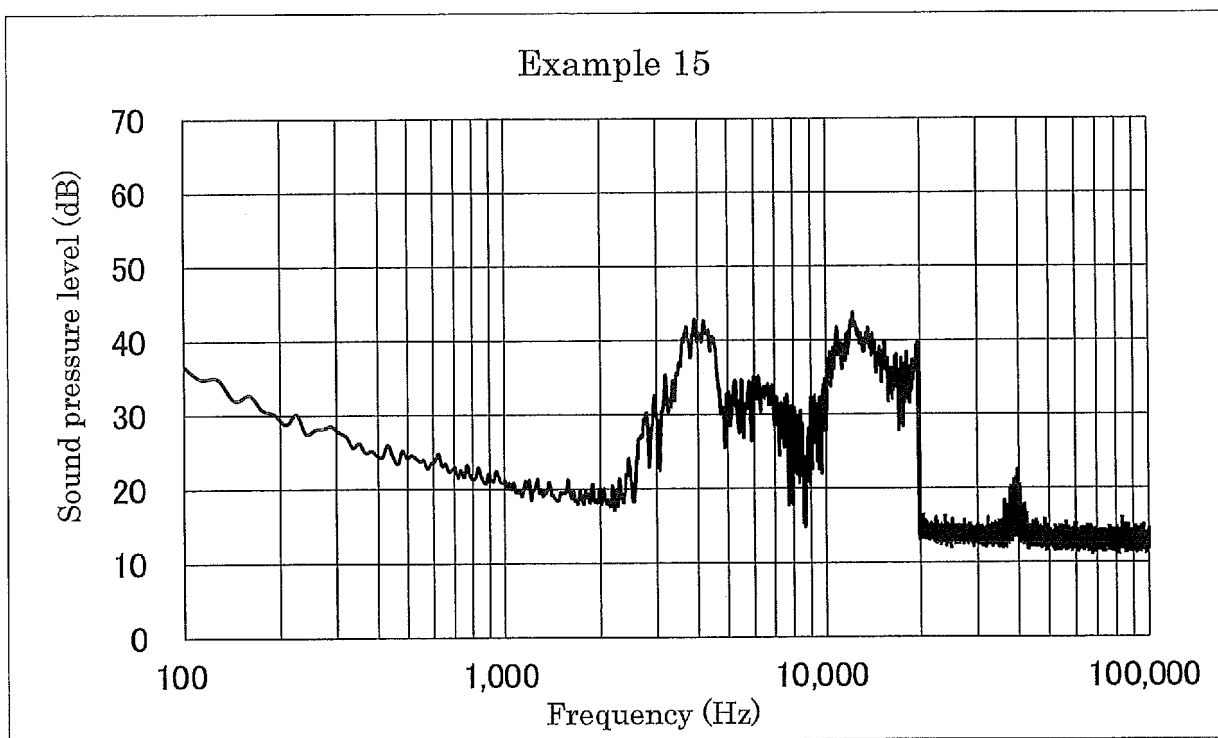


FIG.26

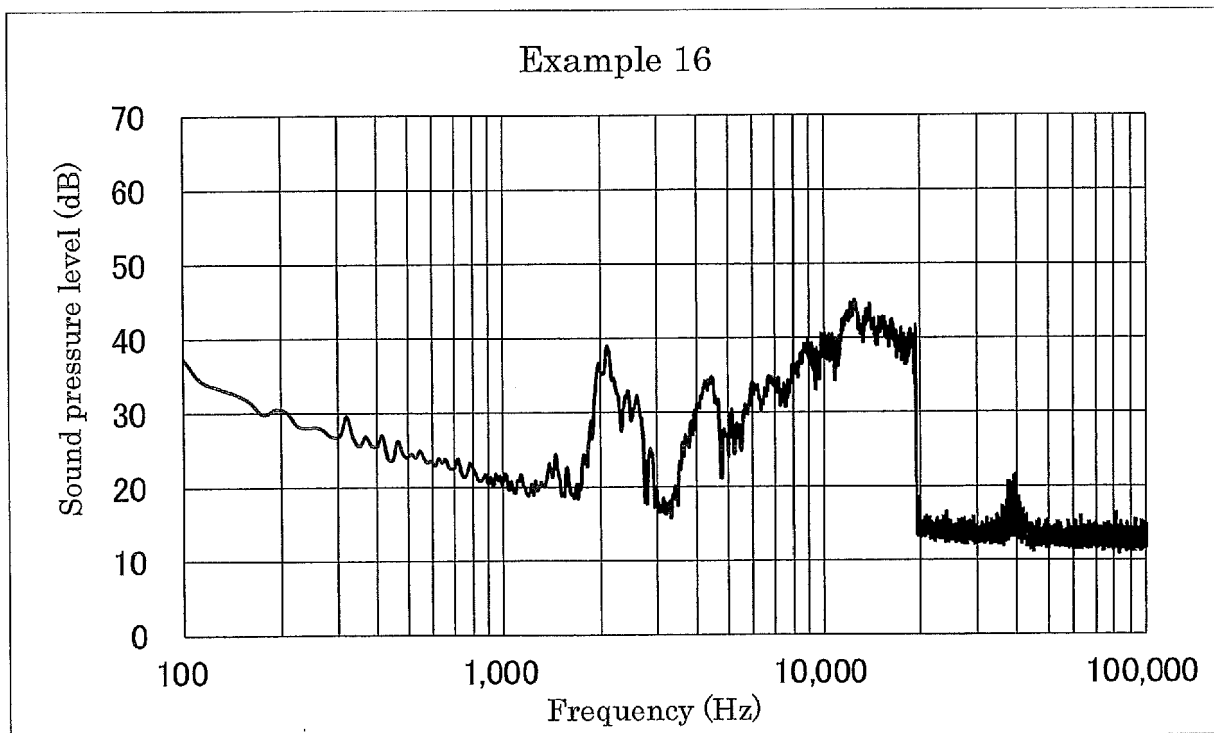


FIG.27

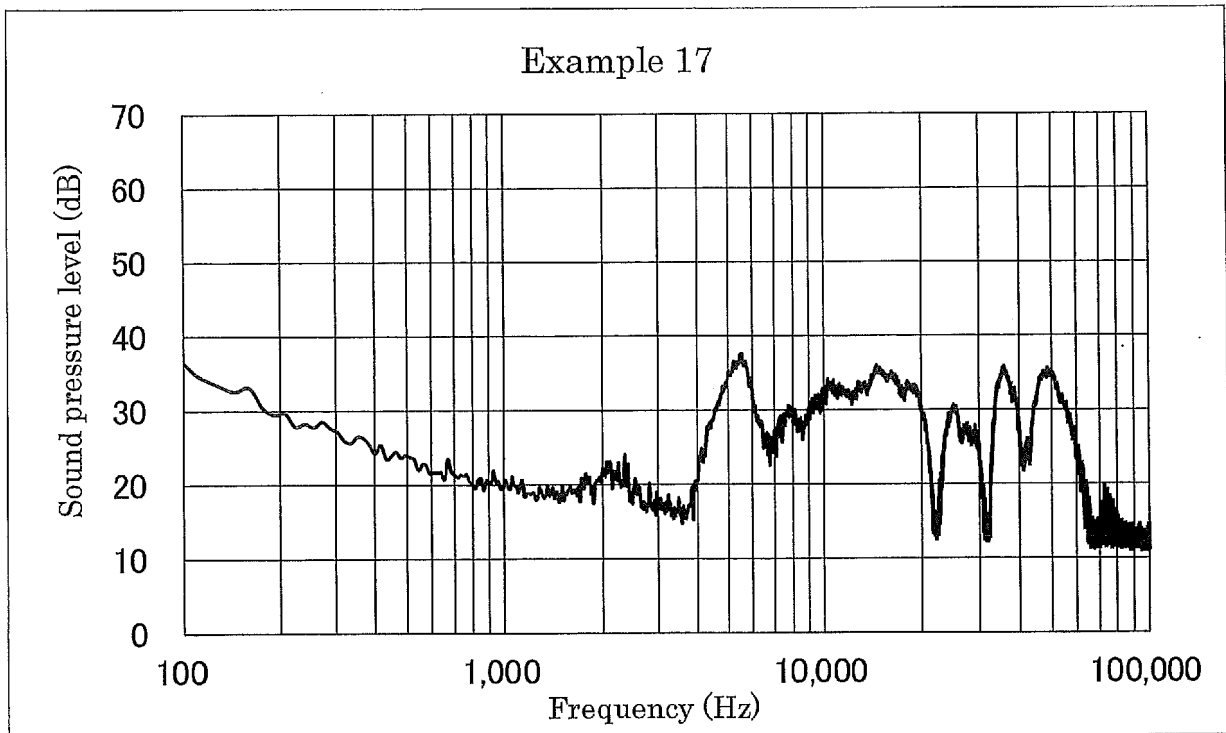


FIG.28

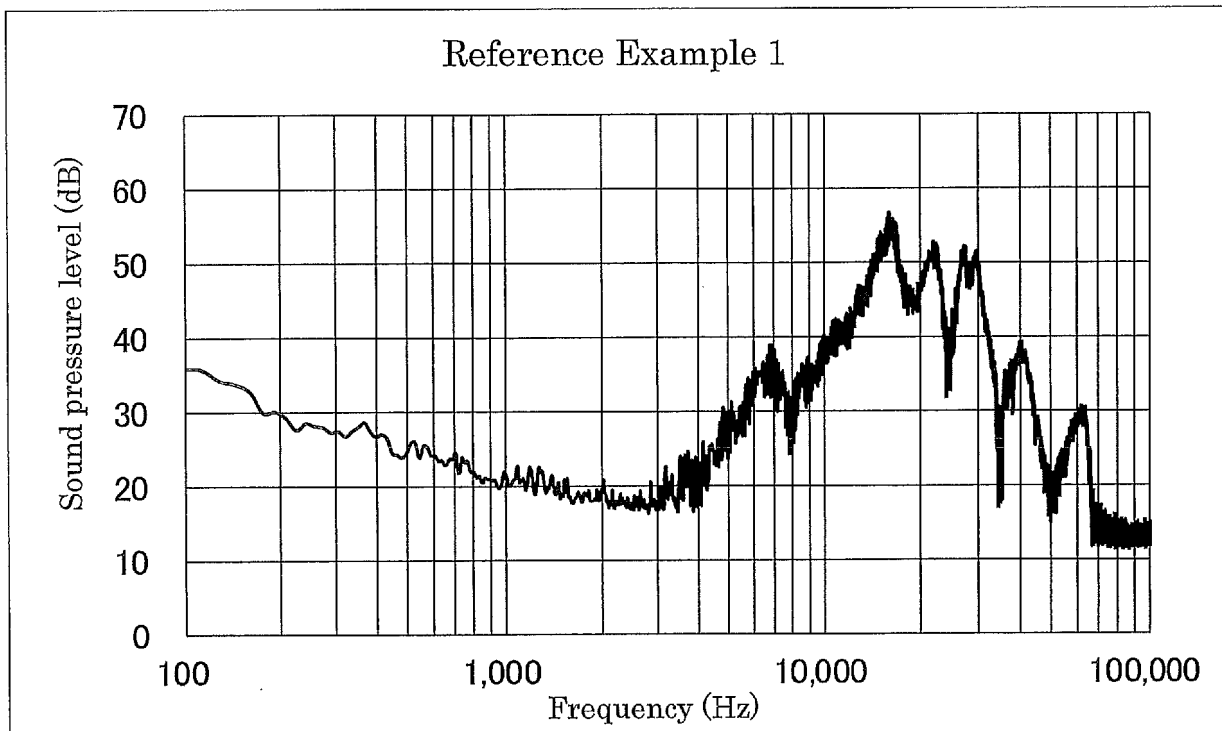
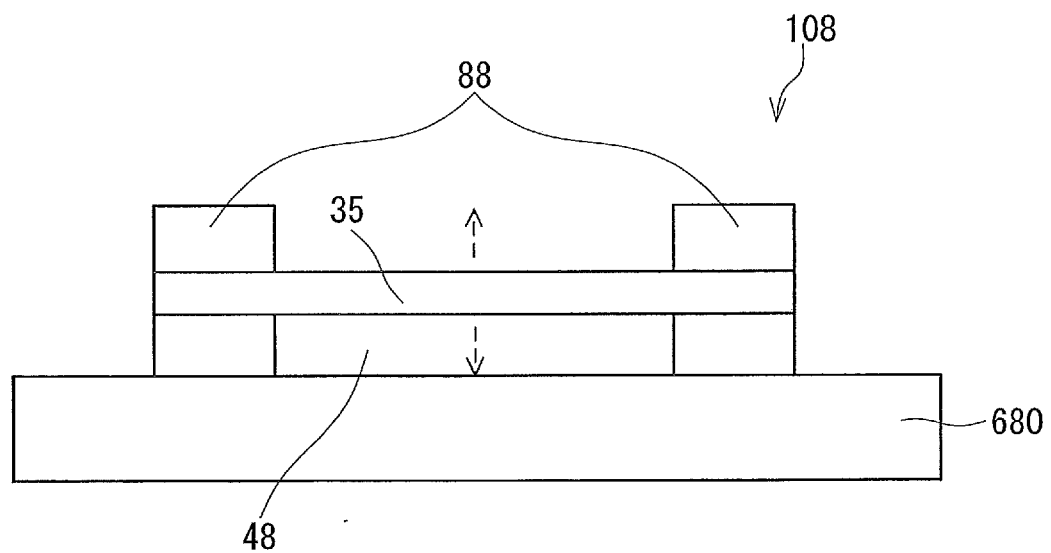
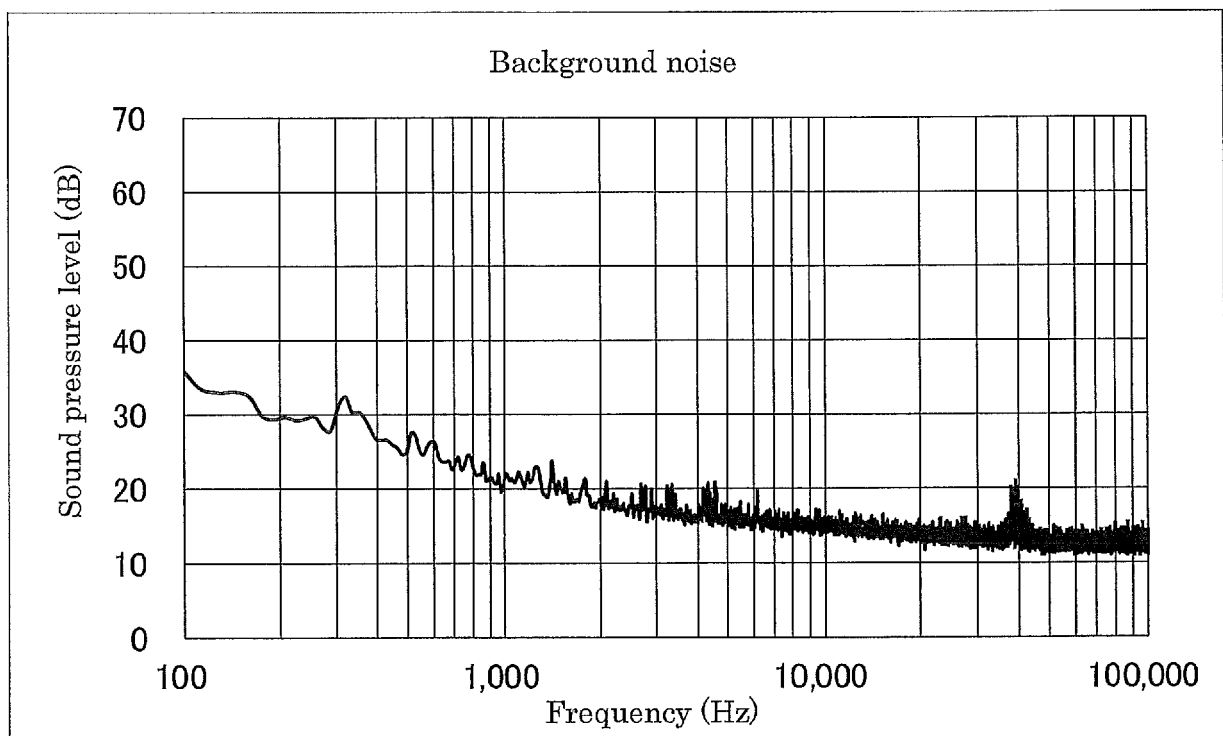


FIG.29



REFERENCES CITED IN THE DESCRIPTION

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